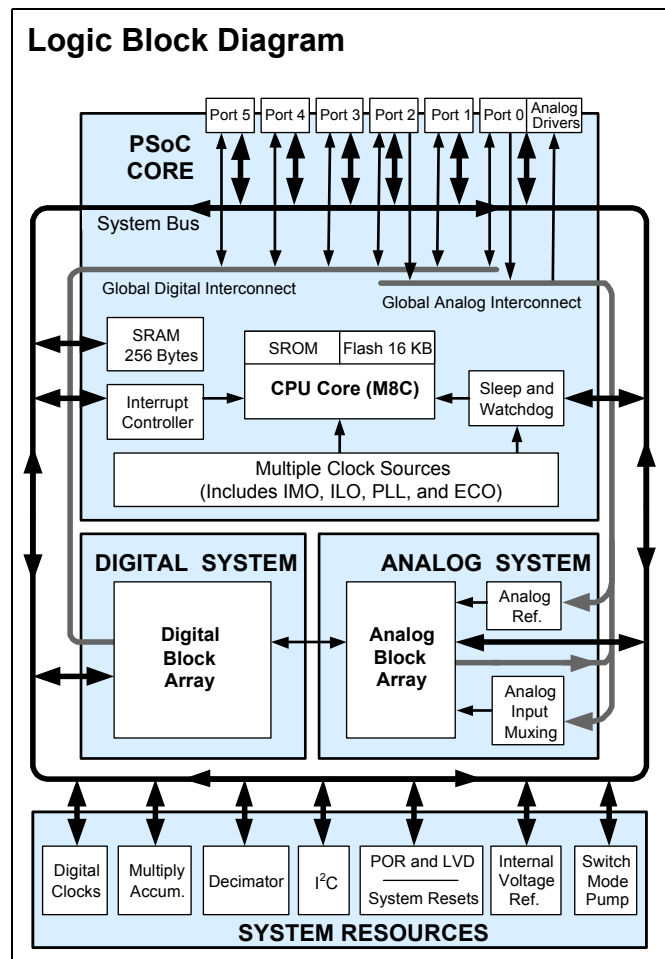


Features

- Powerful Harvard-architecture processor
 - M8C processor speeds to 24 MHz
 - Two 8×8 multiply, 32-bit accumulate
 - Low power at high speed
 - 3.0 V to 5.25 V operating voltage
 - Operating voltages down to 1.0 V using on-chip switch mode pump (SMP)
 - Industrial temperature range: -40 °C to +85 °C
- Advanced peripherals (PSoC[®] blocks)
 - 12 rail-to-rail analog PSoC blocks provide:
 - Up to 14-bit analog-to-digital converters (ADCs)
 - Up to 9-bit digital-to-analog converters (DACs)
 - Programmable gain amplifiers (PGAs)
 - Programmable filters and comparators
 - 16 digital PSoC blocks provide:
 - 8- to 32-bit timers, counters, and pulse-width modulators (PWMs)
 - Cyclical redundancy check (CRC) and pseudo random sequence (PRS) modules
 - Up to four full-duplex universal asynchronous receiver transmitters (UARTs)
 - Multiple serial peripheral interface (SPI) masters or slaves
 - Can connect to all general purpose I/O (GPIO) pins
 - Create complex peripherals by combining blocks
- Precision, programmable clocking
 - Internal ±2.5% 24-/48-MHz oscillator
 - 24/48 MHz with optional 32.768 kHz crystal
 - Optional external oscillator, up to 24 MHz
 - Internal oscillator for watchdog and sleep
- Flexible on-chip memory
 - 32 KB flash program storage 50,000 erase/write cycles
 - 2 KB static random access memory (SRAM) data storage
 - In-System Serial Programming (ISSP)
 - Partial flash updates
 - Flexible protection modes
 - Electrically erasable programmable read-only memory (EEPROM) emulation in flash
- Programmable pin configurations
 - 25-mA sink, 10-mA source on all GPIOs
 - Pull-up, pull-down, High Z, strong, or open drain drive modes on all GPIOs
 - Eight standard analog inputs on GPIOs, plus four additional analog inputs with restricted routing
 - Four 40-mA analog outputs on GPIOs
 - Configurable interrupt on all GPIOs
- Additional system resources
 - I²C slave, master, and multi-master to 400 kHz
 - Watchdog and sleep timers
 - User-configurable low-voltage detection (LVD)
 - Integrated supervisory circuit
 - On-chip precision voltage reference
- Complete development tools
 - Free development software (PSoC Designer™)
 - Full-featured In-Circuit Emulator (ICE) and programmer
 - Full-speed emulation
 - Complex breakpoint structure
 - 128 KB trace memory
 - Complex events
 - C Compilers, assembler, and linker

Logic Block Diagram



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PSoC Functional Overview

The PSoC family consists of many Programmable System-on-Chip Controller devices. These devices are designed to replace multiple traditional microcontroller unit (MCU)-based system components with one, low-cost single-chip programmable device. PSoC devices include configurable blocks of analog and digital logic, as well as programmable interconnects. This architecture allows you to create customized peripheral configurations that match the requirements of each individual application. Additionally, a fast central processing unit (CPU), flash program memory, SRAM data memory, and configurable I/O are included in a range of convenient pinouts and packages.

The PSoC architecture, as illustrated in the [Logic Block Diagram](#) on page 1, consists of four main areas: PSoC core, digital system, analog system, and system resources. Configurable global busing allows all of the device resources to be combined into a complete custom system. The PSoC CY8C29x66 family can have up to five I/O ports that connect to the global digital and analog interconnects, providing access to 8 digital blocks and 12 analog blocks.

PSoC Core

The PSoC Core is a powerful engine that supports a rich feature set. The core includes a CPU, memory, clocks, and configurable GPIOs.

The M8C CPU core is a powerful processor with speeds up to 24 MHz, providing a 4 million instructions per second (MIPS) 8-bit Harvard-architecture microprocessor. The CPU uses an interrupt controller with 17 vectors, to simplify programming of real-time embedded events. Program execution is timed and protected using the included sleep and watchdog timers (WDT).

Memory uses 16 KB of flash for program storage, 256 bytes of SRAM for data storage, and up to 2 KB of EEPROM emulated using the flash. Program flash uses four protection levels on blocks of 64 bytes, allowing customized software information protection (IP).

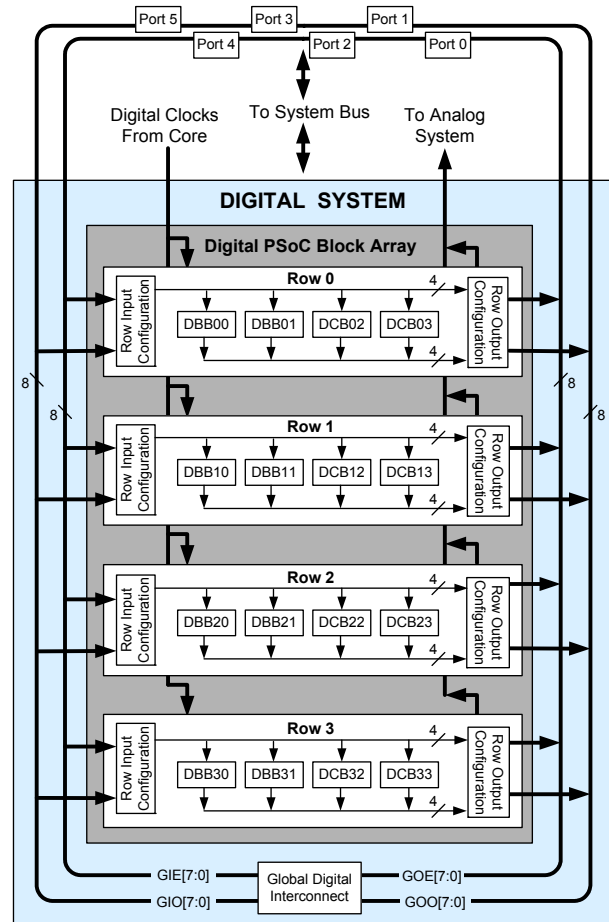
The PSoC device incorporates flexible internal clock generators, including a 24 MHz internal main oscillator (IMO) accurate to 2.5% over temperature and voltage. The 24 MHz IMO can also be doubled to 48 MHz for use by the digital system. A low power 32 kHz internal low speed oscillator (ILO) is provided for the sleep timer and WDT. If crystal accuracy is desired, the 32.768 kHz external crystal oscillator (ECO) is available for use as a real-time clock (RTC) and can optionally generate a crystal-accurate 24 MHz system clock using a PLL. The clocks, together with programmable clock dividers (as a system resource), provide the flexibility to integrate almost any timing requirement into the PSoC device.

PSoC GPIOs provide connection to the CPU, and digital and analog resources of the device. Each pin's drive mode may be selected from eight options, allowing great flexibility in external interfacing. Every pin also has the capability to generate a system interrupt on high level, low level, and change from last read.

Digital System

The digital system is composed of 16 digital PSoC blocks. Each block is an 8-bit resource that can be used alone or combined with other blocks to form 8-, 16-, 24-, and 32-bit peripherals, which are called user modules.

Figure 1. Digital System Block Diagram



Digital peripheral configurations include:

- PWMs (8- to 32-bit)
- PWMs with dead band (8- to 32-bit)
- Counters (8- to 32-bit)
- Timers (8- to 32-bit)
- UART 8-bit with selectable parity (up to 2)
- SPI slave and master (up to 2)
- I²C slave and multi-master (one available as a system resource)
- CRC generator (8- to 32-bit)
- IrDA (up to 2)
- PRS generators (8- to 32-bit)

The digital blocks can be connected to any GPIO through a series of global buses that can route any signal to any pin. The buses also allow for signal multiplexing and for performing logic operations. This configurability frees your designs from the constraints of a fixed peripheral controller.

Digital blocks are provided in rows of four, where the number of blocks varies by PSoC device family. This allows you the optimum choice of system resources for your application. Family resources are shown in the table titled “PSoC Device Characteristics” on page 5.

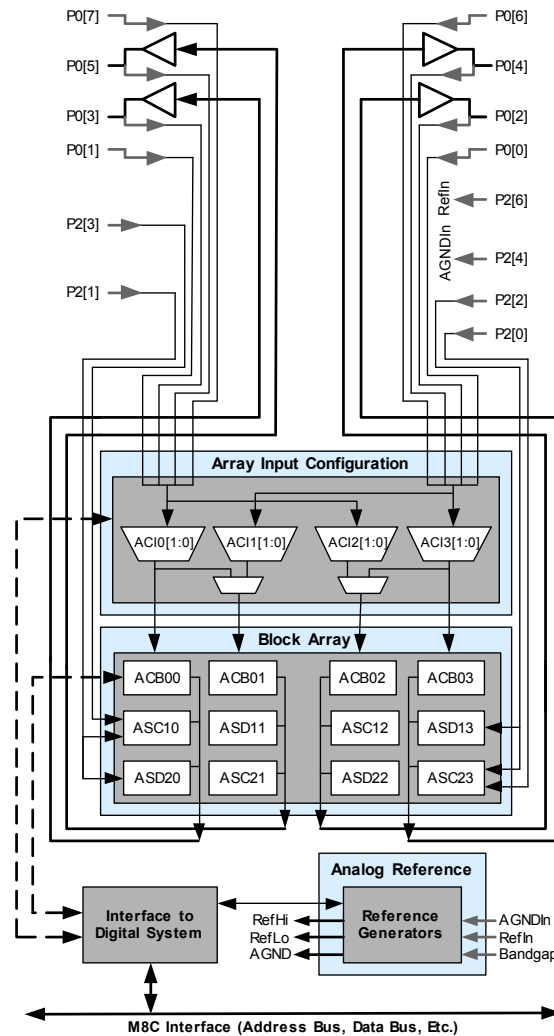
Analog System

The analog system is composed of 12 configurable blocks, each containing an opamp circuit that allows the creation of complex analog signal flows. Analog peripherals are very flexible and can be customized to support specific application requirements. Some of the more common PSoC analog functions (most available as user modules) are:

- ADCs (up to 4, with 6- to 14-bit resolution; selectable as incremental, delta sigma, and SAR)
- Filters (2-, 4-, 6-, and 8-pole band pass, low pass, and notch)
- Amplifiers (up to 4, with selectable gain to 48x)
- Instrumentation amplifiers (up to 2, with selectable gain to 93x)
- Comparators (up to 4, with 16 selectable thresholds)
- DACs (up to 4, with 6- to 9-bit resolution)
- Multiplying DACs (up to 4, with 6- to 9-bit resolution)
- High current output drivers (four with 30-mA drive as a core resource)
- 1.3-V reference (as a system resource)
- DTMF Dialer
- Modulators
- Correlators
- Peak detectors
- Many other topologies possible

Analog blocks are provided in columns of three, which includes one Continuous Time (CT) and two Switched Capacitor (SC) blocks, as shown in Figure 2.

Figure 2. Analog System Block Diagram



Additional System Resources

System resources, some of which were previously listed, provide additional capability useful to complete systems. Additional resources include a multiplier, decimator, switch mode pump, low-voltage detection, and power-on reset (POR).

- Digital clock dividers provide three customizable clock frequencies for use in applications. The clocks can be routed to both the digital and analog systems. Additional clocks can be generated using digital PSoC blocks as clock dividers.
- Multiply accumulate (MAC) provides a fast 8-bit multiplier with 32-bit accumulate, to assist in general math and digital filters.
- The decimator provides a custom hardware filter for digital signal processing applications including the creation of delta sigma ADCs.
- The I²C module provides 100 and 400 kHz communication over two wires. Slave, master, and multi-master modes are all supported.

- LVD interrupts can signal the application of falling voltage levels, while the advanced POR circuit eliminates the need for a system supervisor.
- An internal 1.3-V reference provides an absolute reference for the analog system, including ADCs and DACs.
- An integrated switch mode pump (SMP) generates normal operating voltages from a single 1.2-V battery cell, providing a low cost boost converter.

PSoC Device Characteristics

Depending on your PSoC device characteristics, the digital and analog systems can have 16, 8, or 4 digital blocks and 12, 6, or 4 analog blocks. The following table lists the resources available for specific PSoC device groups. The PSoC device covered by this datasheet is highlighted below.

Table 1. PSoC Device Characteristics

PSoC Part Number	Digital I/O	Digital Rows	Digital Blocks	Analog Inputs	Analog Outputs	Analog Columns	Analog Blocks	SRAM Size	Flash Size
CY8C29x66	up to 64	4	16	12	4	4	12	2 KB	32 KB
CY8C27x43	up to 44	2	8	12	4	4	12	256 Bytes	16 KB
CY8C24x94	49	1	4	48	2	2	6	1 KB	16 KB
CY8C24x23	up to 24	1	4	12	2	2	6	256 Bytes	4 KB
CY8C24x23A	up to 24	1	4	12	2	2	6	256 Bytes	4 KB
CY8C21x34	up to 28	1	4	28	0	2	4 ^[1]	512 Bytes	8 KB
CY8C21x23	16	1	4	8	0	2	4 ^[1]	256 Bytes	4 KB
CY8C20x34	up to 28	0	0	28	0	0	3 ^[2]	512 Bytes	8 KB

Notes

1. Limited analog functionality.
2. Two analog blocks and one CapSense®.

Getting Started

For in depth information, along with detailed programming details, see the *PSoC® Technical Reference Manual*.

For up-to-date ordering, packaging, and electrical specification information, see the latest [PSoC device datasheets](#) on the web.

Application Notes

[Cypress application notes](#) are an excellent introduction to the wide variety of possible PSoC designs.

Development Kits

[PSoC Development Kits](#) are available online from and through a growing number of regional and global distributors, which include Arrow, Avnet, Digi-Key, Farnell, Future Electronics, and Newark.

Training

[Free PSoC technical training](#) (on demand, webinars, and workshops), which is available online via www.cypress.com, covers a wide variety of topics and skill levels to assist you in your designs.

CYPros Consultants

Certified PSoC Consultants offer everything from technical assistance to completed PSoC designs. To contact or become a PSoC Consultant go to the [CYPros Consultants](#) web site.

Solutions Library

Visit our growing [library of solution focused designs](#). Here you can find various application designs that include firmware and hardware design files that enable you to complete your designs quickly.

Technical Support

[Technical support](#) – including a searchable Knowledge Base articles and technical forums – is also available online. If you cannot find an answer to your question, call our Technical Support hotline at 1-800-541-4736.

Development Tools

PSoC Designer is a Microsoft® Windows-based, integrated development environment for the PSoC programmable system-on-chip. The PSoC Designer IDE runs on Windows XP or Windows Vista.

This system provides design database management by project, an integrated debugger with an In-Circuit Emulator (ICE), in-system programming support, and built in support for third party assemblers and C compilers.

PSoC Designer also supports C language compilers developed specifically for the devices in the PSoC family.

PSoC Designer Software Subsystems

System-Level View

In the system-level view you create a model of your system inputs, outputs, and communication interfaces. You define when and how an output device changes state based upon any or all other system devices. PSoC Designer automatically selects one or more programmable controllers that match your system requirements.

PSoC Designer generates all embedded code, then compiles and links it into a programming file for a specific PSoC device.

Chip-Level View

The chip-level view is a more traditional integrated development environment (IDE). Choose a base device to work with and then select different onboard analog and digital components called user modules that use the PSoC blocks. Examples of user modules are ADCs, DACs, amplifiers, and filters. Configure the user modules for your chosen application and connect them to each other and to the proper pins. Then generate your project. This prepopulates your project with application programming interfaces (APIs) and libraries that you can use to program your application.

The device editor also supports easy development of multiple configurations and dynamic reconfiguration. Dynamic configuration allows for changing configurations at run time.

Hybrid Designs

You can begin in the system-level view, allow it to choose and configure your user modules, routing, and generate code. Then you switch to the chip-level view to gain complete control over on-chip resources. All views of the project share a common code editor, builder, and common debug, emulation, and programming tools.

Code Generation Tools

PSoC Designer supports multiple third party C compilers and assemblers. The code generation tools work seamlessly within the PSoC Designer interface and have been tested with a full range of debugging tools.

Assemblers. The assemblers allow assembly code to merge seamlessly with C code. Link libraries automatically use absolute addressing or are compiled in relative mode, and linked with other software modules to get absolute addressing.

C Language Compilers. Our available C language compilers support the PSoC family of devices. The products allow you to create complete C programs for the PSoC family devices.

The optimizing C compilers provide all the features of C tailored to the PSoC architecture. They come complete with embedded libraries providing port and bus operations, standard keypad and display support, and extended math functionality.

Debugger

The PSoC Designer Debugger subsystem provides hardware in-circuit emulation. This allows you to test the program in a physical system while providing an internal view of the PSoC device. Debugger commands allow the designer to read and program and read and write data memory; read and write I/O registers; read and write CPU registers; set and clear breakpoints; and provide program run, halt, and step control. The debugger also allows the designer to create a trace buffer of registers and memory locations of interest.

Online Help System

The online help system displays online, context-sensitive user help. Designed for procedural and quick reference, each functional subsystem has its own context-sensitive help. This system also provides tutorials and links to FAQs and an online support forum to aid the designer in getting started.

In-Circuit Emulator

A low-cost, high-functionality ICE is available for development support. This hardware can program single devices.

The emulator consists of a base unit that connects to the PC by way of a USB port. The base unit is universal and operates with all PSoC devices. Emulation pods for each device family are available separately. The emulation pod takes the place of the PSoC device in the target board and performs full speed (24 MHz) operation.

Designing with PSoC Designer

The development process for the PSoC device differs from that of a traditional fixed-function microprocessor. The configurable analog and digital hardware blocks give the PSoC architecture a unique flexibility that pays dividends in managing specification change during development and lowering inventory costs. These configurable resources, called PSoC blocks, can implement a wide variety of user-selectable functions.

The PSoC development process can be summarized in these four steps:

1. Select components
2. Configure components
3. Organize and connect
4. Generate, verify, and debug

Select Components

Both the system-level and chip-level views provide a library of prebuilt, pretested hardware peripheral components. In the system-level view, these components are called “drivers” and correspond to inputs (a thermistor, for example), outputs (a brushless DC fan, for example), communication interfaces (I²C-bus, for example), and the logic to control how they interact with one another (called valuator).

In the chip-level view, the components are called “user modules”. User modules make selecting and implementing peripheral devices simple, and come in analog, digital, and programmable system-on-chip varieties.

Configure Components

Each of the components you select establishes the basic register settings that implement the selected function. They also provide parameters and properties that allow you to tailor their precise configuration to your particular application. For example, a pulse width modulator (PWM) User Module configures one or more digital PSoC blocks, one for each 8 bits of resolution. The user module parameters permit you to establish the pulse width and duty cycle. Configure the parameters and properties to correspond to your chosen application. Enter values directly or by selecting values from drop-down menus.

Both the system-level drivers and chip-level user modules are documented in datasheets that are viewed directly in the PSoC Designer. These datasheets explain the internal operation of the component and provide performance specifications. Each datasheet describes the use of each user module parameter or driver property, and other information you may need to successfully implement your design.

Organize and Connect

You can build signal chains at the chip level by interconnecting user modules to each other and the I/O pins, or connect system level inputs, outputs, and communication interfaces to each other with valuator functions.

In the system-level view, selecting a potentiometer driver to control a variable speed fan driver and setting up the valuator to control the fan speed based on input from the pot selects, places, routes, and configures a programmable gain amplifier (PGA) to buffer the input from the potentiometer, an ADC to convert the potentiometer’s output to a digital signal, and a PWM to control the fan.

In the chip-level view, perform the selection, configuration, and routing so that you have complete control over the use of all on-chip resources.

Generate, Verify, and Debug

When you are ready to test the hardware configuration or move on to developing code for the project, go to the “Generate Application” step. This causes PSoC Designer to generate source code that automatically configures the device to your specification and provides the software for the system.

Both system-level and chip-level designs generate software based on your design. The chip-level design provides APIs with high level functions to control and respond to hardware events at run time and interrupt service routines that you can adapt as needed. The system-level design also generates a `C main()` program that completely controls the chosen application. It also contains placeholders for custom code at strategic positions allowing you to further refine the software without disrupting the generated code.

A complete code development environment allows you to develop and customize your applications in C, assembly language, or both.

The last step in the development process takes place inside PSoC Designer’s debugger subsystem. The debugger downloads the HEX image to the ICE where it runs at full speed. Debugger capabilities rival those of systems costing many times more. In addition to traditional single-step, run-to-breakpoint and watch-variable features, the debugger provides a large trace buffer and allows you define complex breakpoint events that include monitoring address and data bus values, memory locations and external signals.

Pinouts

The CY8C29x66 PSoC device is available in a variety of packages which are listed and illustrated in the following tables. Every port pin (labeled with a "P") is capable of Digital I/O. However, V_{SS}, V_{DD}, SMP, and XRES are not capable of Digital I/O.

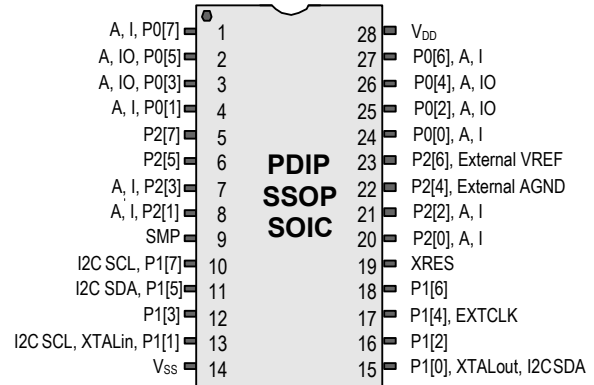
28-Pin Part Pinout

Table 2. 28-Pin Part Pinout (PDIP, SSOP, SOIC)

Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	I/O	I	P0[7]	Analog column mux input
2	I/O	I/O	P0[5]	Analog column mux input and column output
3	I/O	I/O	P0[3]	Analog column mux input and column output
4	I/O	I	P0[1]	Analog column mux input
5	I/O		P2[7]	
6	I/O		P2[5]	
7	I/O	I	P2[3]	Direct switched capacitor block input
8	I/O	I	P2[1]	Direct switched capacitor block input
9	Power		SMP	Switch Mode Pump (SMP) connection to external components required
10	I/O		P1[7]	I ² C Serial Clock (SCL)
11	I/O		P1[5]	I ² C Serial Data (SDA)
12	I/O		P1[3]	
13	I/O		P1[1]	Crystal (XTALin), I ² C Serial Clock (SCL), ISSP-SCLK ^[3]
14	Power		V _{SS}	Ground connection
15	I/O		P1[0]	Crystal (XTALout), I ² C Serial Data (SDA), ISSP-SDATA ^[3]
16	I/O		P1[2]	
17	I/O		P1[4]	Optional External Clock Input (EXTCLK)
18	I/O		P1[6]	
19	Input		XRES	Active high external reset with internal pull down
20	I/O	I	P2[0]	Direct switched capacitor block input
21	I/O	I	P2[2]	Direct switched capacitor block input
22	I/O		P2[4]	External Analog Ground (AGND)
23	I/O		P2[6]	External Voltage Reference (VREF)
24	I/O	I	P0[0]	Analog column mux input
25	I/O	I/O	P0[2]	Analog column mux input and column output
26	I/O	I/O	P0[4]	Analog column mux input and column output
27	I/O	I	P0[6]	Analog column mux input
28	Power		V _{DD}	Supply voltage

LEGEND: A = Analog, I = Input, and O = Output.

Figure 3. CY8C29466 28-Pin PSoC Device



Note

3. These are the ISSP pins, which are not High Z at Power On Reset (POR). See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

44-Pin Part Pinout

Table 3. 44-Pin Part Pinout (TQFP)

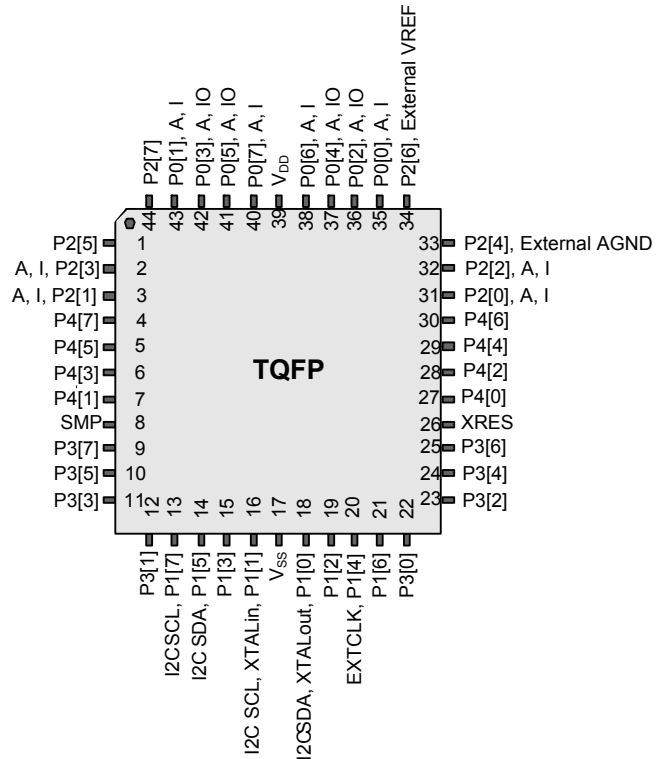
Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	I/O		P2[5]	
2	I/O	I	P2[3]	Direct switched capacitor block input
3	I/O	I	P2[1]	Direct switched capacitor block input
4	I/O		P4[7]	
5	I/O		P4[5]	
6	I/O		P4[3]	
7	I/O		P4[1]	
8	Power		SMP	Switch Mode Pump (SMP) connection to external components required
9	I/O		P3[7]	
10	I/O		P3[5]	
11	I/O		P3[3]	
12	I/O		P3[1]	
13	I/O		P1[7]	I ² C SCL
14	I/O		P1[5]	I ² C SDA
15	I/O		P1[3]	
16	I/O		P1[1]	Crystal (XTALin), I ² C SCL, ISSP-SCLK ^[4]
17	Power		V _{SS}	Ground connection
18	I/O		P1[0]	Crystal (XTALout), I ² C SDA, ISSP-SDATA ^[4]
19	I/O		P1[2]	
20	I/O		P1[4]	Optional EXTCLK
21	I/O		P1[6]	
22	I/O		P3[0]	
23	I/O		P3[2]	
24	I/O		P3[4]	
25	I/O		P3[6]	
26	Input		XRES	Active high external reset with internal pull down
27	I/O		P4[0]	
28	I/O		P4[2]	
29	I/O		P4[4]	
30	I/O		P4[6]	
31	I/O	I	P2[0]	Direct switched capacitor block input
32	I/O	I	P2[2]	Direct switched capacitor block input
33	I/O		P2[4]	External Analog Ground (AGND)
34	I/O		P2[6]	External Voltage Reference (VREF)
35	I/O	I	P0[0]	Analog column mux input
36	I/O	I/O	P0[2]	Analog column mux input and column output
37	I/O	I/O	P0[4]	Analog column mux input and column output
38	I/O	I	P0[6]	Analog column mux input
39	Power		V _{DD}	Supply voltage
40	I/O	I	P0[7]	Analog column mux input
41	I/O	I/O	P0[5]	Analog column mux input and column output
42	I/O	I/O	P0[3]	Analog column mux input and column output
43	I/O	I	P0[1]	Analog column mux input
44	I/O		P2[7]	

LEGEND: A = Analog, I = Input, and O = Output.

Note

4. These are the ISSP pins, which are not High Z at POR. See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

Figure 4. CY8C29566 44-Pin PSoC Device



48-Pin Part Pinout

Table 4. 48-Pin Part Pinout (SSOP)

Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	I/O	I	P0[7]	Analog column mux input
2	I/O	I/O	P0[5]	Analog column mux input and column output
3	I/O	I/O	P0[3]	Analog column mux input and column output
4	I/O	I	P0[1]	Analog column mux input
5	I/O		P2[7]	
6	I/O		P2[5]	
7	I/O	I	P2[3]	Direct switched capacitor block input
8	I/O	I	P2[1]	Direct switched capacitor block input
9	I/O		P4[7]	
10	I/O		P4[5]	
11	I/O		P4[3]	
12	I/O		P4[1]	
13	Power		SMP	Switch Mode Pump (SMP) connection to external components required
14	I/O		P3[7]	
15	I/O		P3[5]	
16	I/O		P3[3]	
17	I/O		P3[1]	
18	I/O		P5[3]	
19	I/O		P5[1]	
20	I/O		P1[7]	I ² C SCL
21	I/O		P1[5]	I ² C SDA
22	I/O		P1[3]	
23	I/O		P1[1]	Crystal (XTALin), I ² C SCL, ISSP-SCLK ^[5]
24	Power		V _{SS}	Ground connection
25	I/O		P1[0]	Crystal (XTALout), I ² C SDA, ISSP-SDATA ^[5]
26	I/O		P1[2]	
27	I/O		P1[4]	Optional EXTCLK
28	I/O		P1[6]	
29	I/O		P5[0]	
30	I/O		P5[2]	
31	I/O		P3[0]	
32	I/O		P3[2]	
33	I/O		P3[4]	
34	I/O		P3[6]	
35	Input		XRES	Active high external reset with internal pull down
36	I/O		P4[0]	
37	I/O		P4[2]	
38	I/O		P4[4]	
39	I/O		P4[6]	
40	I/O	I	P2[0]	Direct switched capacitor block input
41	I/O	I	P2[2]	Direct switched capacitor block input
42	I/O		P2[4]	External Analog Ground (AGND)
43	I/O		P2[6]	External Voltage Reference (VREF)
44	I/O	I	P0[0]	Analog column mux input
45	I/O	I/O	P0[2]	Analog column mux input and column output
46	I/O	I/O	P0[4]	Analog column mux input and column output
47	I/O	I	P0[6]	Analog column mux input
48	Power		V _{DD}	Supply voltage

LEGEND: A = Analog, I = Input, and O = Output.

Note

5. These are the ISSP pins, which are not High Z at POR. See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

Figure 5. CY8C29666 48-Pin PSoC Device

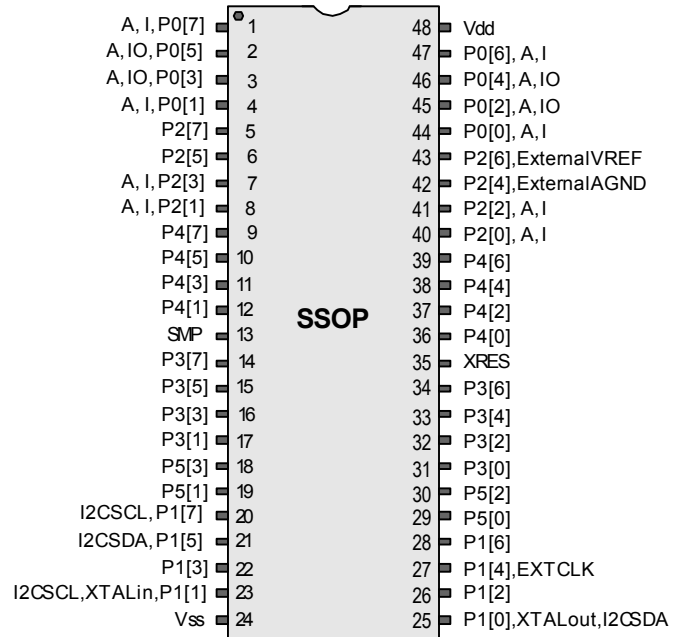


Table 5. 48-Pin Part Pinout (QFN)^[7]

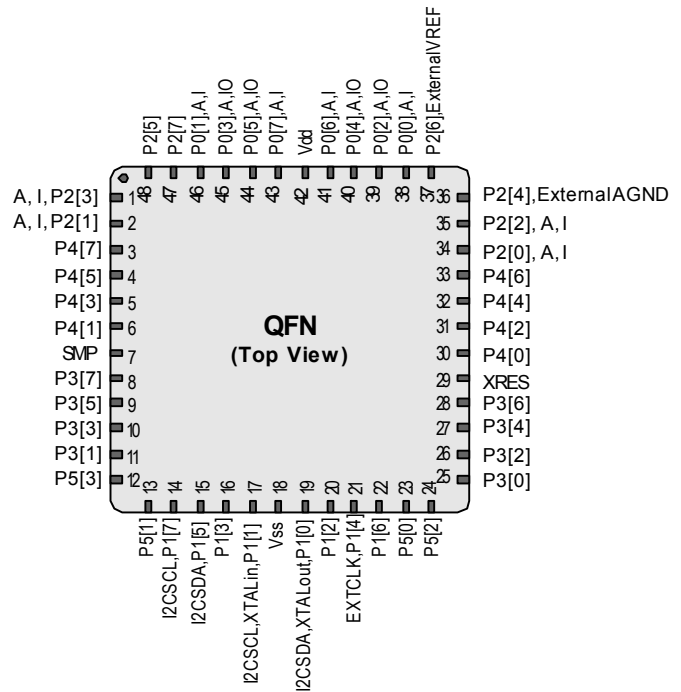
Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	I/O	I	P2[3]	Direct switched capacitor block input
2	I/O	I	P2[1]	Direct switched capacitor block input
3	I/O		P4[7]	
4	I/O		P4[5]	
5	I/O		P4[3]	
6	I/O		P4[1]	
7	Power		SMP	Switch Mode Pump (SMP) connection to external components required
8	I/O		P3[7]	
9	I/O		P3[5]	
10	I/O		P3[3]	
11	I/O		P3[1]	
12	I/O		P5[3]	
13	I/O		P5[1]	
14	I/O		P1[7]	I ² C SCL
15	I/O		P1[5]	I ² C SDA
16	I/O		P1[3]	
17	I/O		P1[1]	Crystal (XTALin), I ² C SCL, ISSP-SCLK ^[6]
18	Power		V _{SS}	Ground connection
19	I/O		P1[0]	Crystal (XTALout), I ² C SDA, ISSP-SDATA ^[6]
20	I/O		P1[2]	
21	I/O		P1[4]	Optional EXTCLK
22	I/O		P1[6]	
23	I/O		P5[0]	
24	I/O		P5[2]	
25	I/O		P3[0]	
26	I/O		P3[2]	
27	I/O		P3[4]	
28	I/O		P3[6]	
29	Input		XRES	Active high external reset with internal pull down
30	I/O		P4[0]	
31	I/O		P4[2]	
32	I/O		P4[4]	
33	I/O		P4[6]	
34	I/O	I	P2[0]	Direct switched capacitor block input
35	I/O	I	P2[2]	Direct switched capacitor block input
36	I/O		P2[4]	External Analog Ground (AGND)
37	I/O		P2[6]	External Voltage Reference (VREF)
38	I/O	I	P0[0]	Analog column mux input
39	I/O	I/O	P0[2]	Analog column mux input and column output
40	I/O	I/O	P0[4]	Analog column mux input and column output
41	I/O	I	P0[6]	Analog column mux input
42	Power		V _{DD}	Supply voltage
43	I/O	I	P0[7]	Analog column mux input
44	I/O	I/O	P0[5]	Analog column mux input and column output
45	I/O	I/O	P0[3]	Analog column mux input and column output
46	I/O	I	P0[1]	Analog column mux input
47	I/O		P2[7]	
48	I/O		P2[5]	

LEGEND: A = Analog, I = Input, and O = Output.

Notes

- These are the ISSP pins, which are not High Z at POR. See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.
- The QFN package has a center pad that must be connected to ground (V_{SS}).

Figure 6. CY8C29666 48-Pin PSoC Device



100-Pin Part Pinout

Table 6. 100-Pin Part Pinout (TQFP)

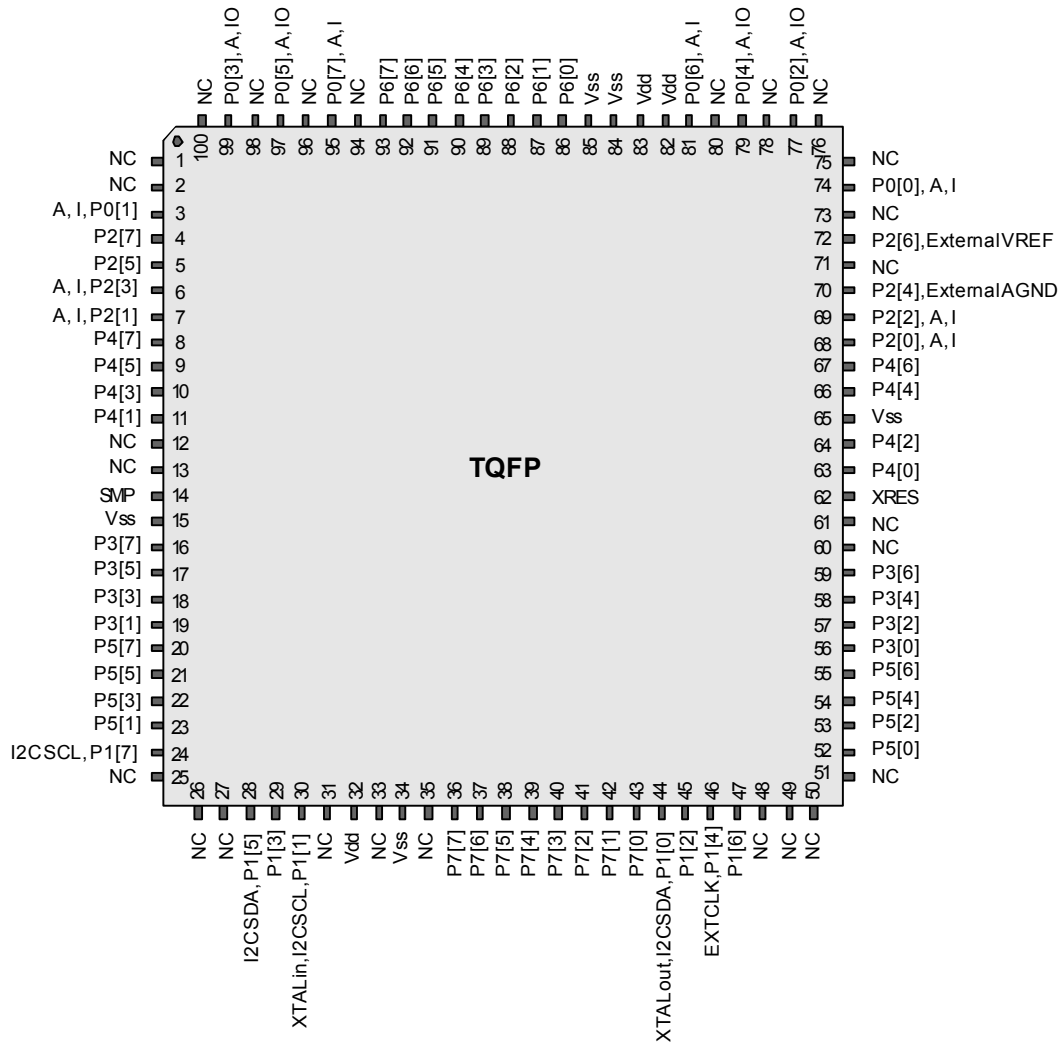
Pin No.	Type		Name	Description	Pin No.	Type		Name	Description
	Digital	Analog				Digital	Analog		
1			NC	No connection	51			NC	No connection
2			NC	No connection	52	I/O		P5[0]	
3	I/O	I	P0[1]	Analog column mux input	53	I/O		P5[2]	
4	I/O		P2[7]		54	I/O		P5[4]	
5	I/O		P2[5]		55	I/O		P5[6]	
6	I/O	I	P2[3]	Direct switched capacitor block input	56	I/O		P3[0]	
7	I/O	I	P2[1]	Direct switched capacitor block input	57	I/O		P3[2]	
8	I/O		P4[7]		58	I/O		P3[4]	
9	I/O		P4[5]		59	I/O		P3[6]	
10	I/O		P4[3]		60			NC	No connection
11	I/O		P4[1]		61			NC	No connection
12			NC	No connection	62		Input	XRES	Active high external reset with internal pull down
13			NC	No connection	63	I/O		P4[0]	
14		Power	SMP	Switch Mode Pump (SMP) connection to external components required	64	I/O		P4[2]	
15		Power	V _{SS}	Ground connection	65		Power	V _{SS}	Ground connection
16	I/O		P3[7]		66	I/O		P4[4]	
17	I/O		P3[5]		67	I/O		P4[6]	
18	I/O		P3[3]		68	I/O	I	P2[0]	Direct switched capacitor block input
19	I/O		P3[1]		69	I/O	I	P2[2]	Direct switched capacitor block input
20	I/O		P5[7]		70	I/O		P2[4]	External Analog Ground (AGND)
21	I/O		P5[5]		71			NC	No connection
22	I/O		P5[3]		72	I/O		P2[6]	External Voltage Reference (VREF)
23	I/O		P5[1]		73			NC	No connection
24	I/O		P1[7]	I ² C SCL	74	I/O	I	P0[0]	Analog column mux input
25			NC	No connection	75			NC	No connection
26			NC	No connection	76			NC	No connection
27			NC	No connection	77	I/O	I/O	P0[2]	Analog column mux input and column output
28	I/O		P1[5]	I ² C SDA	78			NC	No connection
29	I/O		P1[3]		79	I/O	I/O	P0[4]	Analog column mux input and column output
30	I/O		P1[1]	Crystal (XTAL _{in}), I ² C Serial Clock (SCL), ISSP-SCLK ⁸	80			NC	No connection
31			NC	No connection	81	I/O	I	P0[6]	Analog column mux input
32		Power	V _{DD}	Supply voltage	82		Power	V _{DD}	Supply voltage
33			NC	No connection	83		Power	V _{DD}	Supply voltage
34		Power	V _{SS}	Ground connection	84		Power	V _{SS}	Ground connection
35			NC	No connection	85		Power	V _{SS}	Ground connection
36	I/O		P7[7]		86	I/O		P6[0]	
37	I/O		P7[6]		87	I/O		P6[1]	
38	I/O		P7[5]		88	I/O		P6[2]	
39	I/O		P7[4]		89	I/O		P6[3]	
40	I/O		P7[3]		90	I/O		P6[4]	
41	I/O		P7[2]		91	I/O		P6[5]	
42	I/O		P7[1]		92	I/O		P6[6]	
43	I/O		P7[0]		93	I/O		P6[7]	
44	I/O		P1[0]	Crystal (XTAL _{out}), I ² C Serial Data (SDA), ISSP-SDATA ⁸	94			NC	No connection
45	I/O		P1[2]		95	I/O	I	P0[7]	Analog column mux input
46	I/O		P1[4]	Optional EXTCLK	96			NC	No connection
47	I/O		P1[6]		97	I/O	I/O	P0[5]	Analog column mux input and column output
48			NC	No connection	98			NC	No connection
49			NC	No connection	99	I/O	I/O	P0[3]	Analog column mux input and column output
50			NC	No connection	100			NC	No connection

LEGEND: A = Analog, I = Input, and O = Output.

Note

8. These are the ISSP pins, which are not High Z at POR. See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

Figure 7. CY8C29866 100-Pin PSoC Device



100-Pin Part Pinout (On-Chip Debug)

The 100-pin TQFP part is for the CY8C29000 On-Chip Debug (OCD) PSoC device.

Note OCD parts are only used for in-circuit debugging. OCD parts are NOT available for production

Table 7. 100-Pin OCD Part Pinout (TQFP)

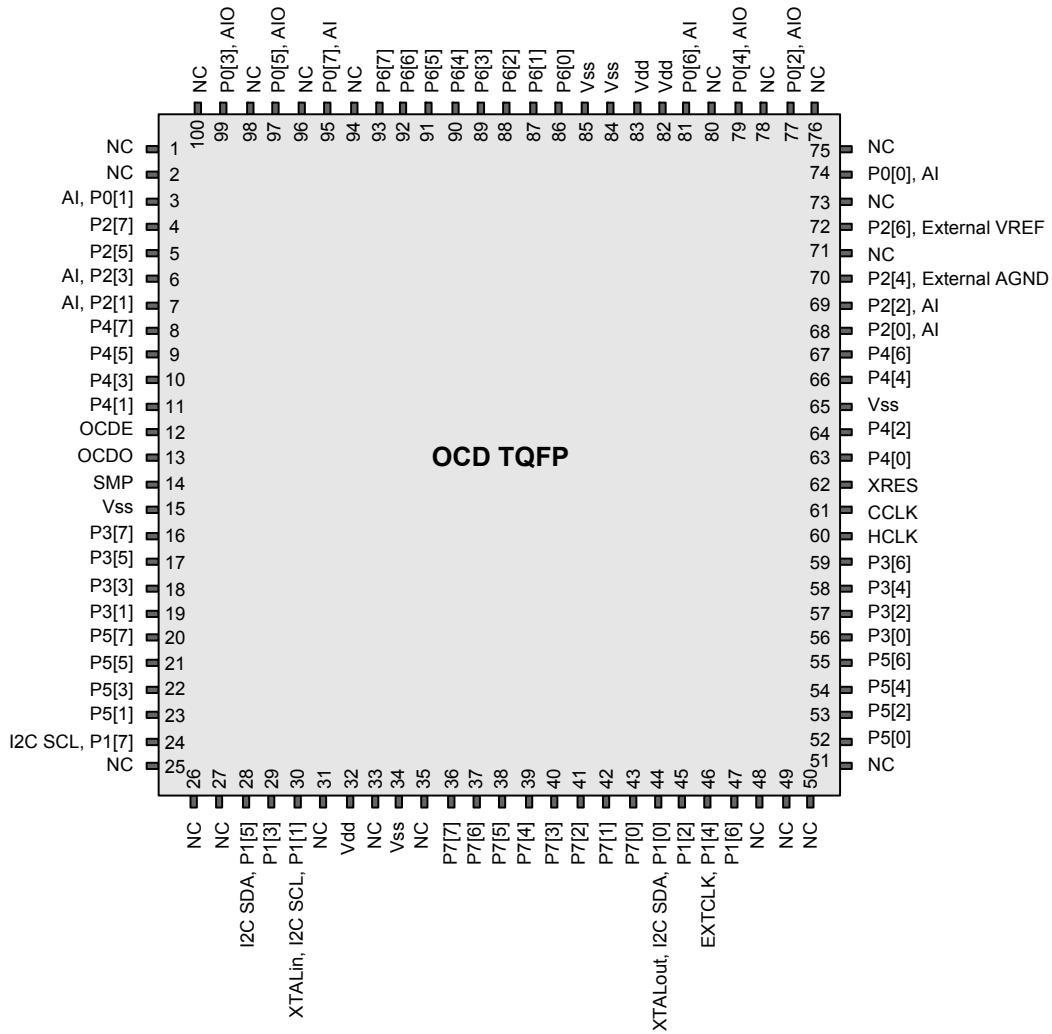
Pin No.	Digital	Analog	Name	Description	Pin No.	Digital	Analog	Name	Description
1			NC	No internal connection	51			NC	No internal connection
2			NC	No internal connection	52	I/O		P5[0]	
3	I/O	I	P0[1]	Analog column mux input	53	I/O		P5[2]	
4	I/O		P2[7]		54	I/O		P5[4]	
5	I/O		P2[5]		55	I/O		P5[6]	
6	I/O	I	P2[3]	Direct switched capacitor block input	56	I/O		P3[0]	
7	I/O	I	P2[1]	Direct switched capacitor block input	57	I/O		P3[2]	
8	I/O		P4[7]		58	I/O		P3[4]	
9	I/O		P4[5]		59	I/O		P3[6]	
10	I/O		P4[3]		60			HCLK	OCD high speed clock output
11	I/O		P4[1]		61			CCLK	OCD CPU clock output
12			OCDE	OCD even data I/O	62	Input		XRES	Active high pin reset with internal pull down
13			OCDO	OCD odd data output	63	I/O		P4[0]	
14	Power		SMP	Switch Mode Pump (SMP) connection to required external components	64	I/O		P4[2]	
15	Power		V _{SS}	Ground connection	65	Power		V _{SS}	Ground connection
16	I/O		P3[7]		66	I/O		P4[4]	
17	I/O		P3[5]		67	I/O		P4[6]	
18	I/O		P3[3]		68	I/O	I	P2[0]	Direct switched capacitor block input
19	I/O		P3[1]		69	I/O	I	P2[2]	Direct switched capacitor block input
20	I/O		P5[7]		70	I/O		P2[4]	External Analog Ground (AGND) input
21	I/O		P5[5]		71			NC	No internal connection
22	I/O		P5[3]		72	I/O		P2[6]	External Voltage Reference (VREF) input
23	I/O		P5[1]		73			NC	No internal connection
24	I/O		P1[7]	I ² C SCL	74	I/O	I	P0[0]	Analog column mux input
25			NC	No internal connection	75			NC	No internal connection
26			NC	No internal connection	76			NC	No internal connection
27			NC	No internal connection	77	I/O	I/O	P0[2]	Analog column mux input and column output
28	I/O		P1[5]	I ² C SDA	78			NC	No internal connection
29	I/O		P1[3]	I _{FMTTEST}	79	I/O	I/O	P0[4]	Analog column mux input and column output, V _{REF}
30	I/O		P1[1] ⁹	Crystal (XTALin), I ² C SCL, TC SCLK.	80			NC	No internal connection
31			NC	No internal connection	81	I/O	I	P0[6]	Analog column mux input
32	Power		V _{DD}	Supply voltage	82	Power		V _{DD}	Supply voltage
33			NC	No internal connection	83	Power		V _{DD}	Supply voltage
34	Power		V _{SS}	Ground connection	84	Power		V _{SS}	Ground connection
35			NC	No internal connection	85	Power		V _{SS}	Ground connection
36	I/O		P7[7]		86	I/O		P6[0]	
37	I/O		P7[6]		87	I/O		P6[1]	
38	I/O		P7[5]		88	I/O		P6[2]	
39	I/O		P7[4]		89	I/O		P6[3]	
40	I/O		P7[3]		90	I/O		P6[4]	
41	I/O		P7[2]		91	I/O		P6[5]	
42	I/O		P7[1]		92	I/O		P6[6]	
43	I/O		P7[0]		93	I/O		P6[7]	
44	I/O		P1[0]*	Crystal (XTALout), I ² C SDA, TC SDATA	94			NC	No internal connection
45	I/O		P1[2]	V _{FMTTEST}	95		I	P0[7]	Analog column mux input
46	I/O		P1[4]	Optional External Clock Input (EXTCLK)	96			NC	No internal connection
47	I/O		P1[6]		97	I/O	I/O	P0[5]	Analog column mux input and column output
48			NC	No internal connection	98			NC	No internal connection
49			NC	No internal connection	99	I/O	I/O	P0[3]	Analog column mux input and column output
50			NC	No internal connection	100			NC	No internal connection

LEGEND A = Analog, I = Input, O = Output, NC = No Connection, TC/TM: Test.

Note

9. ISSP pin which is not High-Z at POR.

Figure 8. CY8C29000 OCD (Not for Production)



Register Reference

This section lists the registers of the CY8C29x66 PSoC device. For detailed register information, refer to the *PSoC Programmable System-on-Chip Technical Reference Manual*.

Register Conventions

The register conventions specific to this section are listed in [Table 8](#).

Table 8. Register Conventions

Convention	Description
R	Read register or bit(s)
W	Write register or bit(s)
L	Logical register or bit(s)
C	Clearable register or bit(s)
#	Access is bit specific

Register Mapping Tables

The PSoC device has a total register address space of 512 bytes. The register space is referred to as I/O space and is divided into two banks. The XO1 bit in the Flag register (CPU_F) determines which bank the user is currently in. When the XO1 bit is set the user is in Bank 1.

Note In the register mapping tables, blank fields are reserved and should not be accessed.

Table 9. Register Map Bank 0 Table: User Space

Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access
PRT0DR	00	RW	DBB20DR0	40	#	ASC10CR0	80	RW	RD12RI	C0	RW
PRT0IE	01	RW	DBB20DR1	41	W	ASC10CR1	81	RW	RD12SYN	C1	RW
PRT0GS	02	RW	DBB20DR2	42	RW	ASC10CR2	82	RW	RD12IS	C2	RW
PRT0DM2	03	RW	DBB20CR0	43	#	ASC10CR3	83	RW	RD12LT0	C3	RW
PRT1DR	04	RW	DBB21DR0	44	#	ASD11CR0	84	RW	RD12LT1	C4	RW
PRT1IE	05	RW	DBB21DR1	45	W	ASD11CR1	85	RW	RD12RO0	C5	RW
PRT1GS	06	RW	DBB21DR2	46	RW	ASD11CR2	86	RW	RD12RO1	C6	RW
PRT1DM2	07	RW	DBB21CR0	47	#	ASD11CR3	87	RW		C7	
PRT2DR	08	RW	DCB22DR0	48	#	ASC12CR0	88	RW	RD13RI	C8	RW
PRT2IE	09	RW	DCB22DR1	49	W	ASC12CR1	89	RW	RD13SYN	C9	RW
PRT2GS	0A	RW	DCB22DR2	4A	RW	ASC12CR2	8A	RW	RD13IS	CA	RW
PRT2DM2	0B	RW	DCB22CR0	4B	#	ASC12CR3	8B	RW	RD13LT0	CB	RW
PRT3DR	0C	RW	DCB23DR0	4C	#	ASD13CR0	8C	RW	RD13LT1	CC	RW
PRT3IE	0D	RW	DCB23DR1	4D	W	ASD13CR1	8D	RW	RD13RO0	CD	RW
PRT3GS	0E	RW	DCB23DR2	4E	RW	ASD13CR2	8E	RW	RD13RO1	CE	RW
PRT3DM2	0F	RW	DCB23CR0	4F	#	ASD13CR3	8F	RW		CF	
PRT4DR	10	RW	DBB30DR0	50	#	ASD20CR0	90	RW	CUR_PP	D0	RW
PRT4IE	11	RW	DBB30DR1	51	W	ASD20CR1	91	RW	STK_PP	D1	RW
PRT4GS	12	RW	DBB30DR2	52	RW	ASD20CR2	92	RW		D2	
PRT4DM2	13	RW	DBB30CR0	53	#	ASD20CR3	93	RW	IDX_PP	D3	RW
PRT5DR	14	RW	DBB31DR0	54	#	ASC21CR0	94	RW	MVR_PP	D4	RW
PRT5IE	15	RW	DBB31DR1	55	W	ASC21CR1	95	RW	MVW_PP	D5	RW
PRT5GS	16	RW	DBB31DR2	56	RW	ASC21CR2	96	RW	I2C_CFG	D6	RW
PRT5DM2	17	RW	DBB31CR0	57	#	ASC21CR3	97	RW	I2C_SCR	D7	#
PRT6DR	18	RW	DCB32DR0	58	#	ASD22CR0	98	RW	I2C_DR	D8	RW
PRT6IE	19	RW	DCB32DR1	59	W	ASD22CR1	99	RW	I2C_MSCR	D9	#
PRT6GS	1A	RW	DCB32DR2	5A	RW	ASD22CR2	9A	RW	INT_CLR0	DA	RW
PRT6DM2	1B	RW	DCB32CR0	5B	#	ASD22CR3	9B	RW	INT_CLR1	DB	RW
PRT7DR	1C	RW	DCB33DR0	5C	#	ASC23CR0	9C	RW	INT_CLR2	DC	RW
PRT7IE	1D	RW	DCB33DR1	5D	W	ASC23CR1	9D	RW	INT_CLR3	DD	RW
PRT7GS	1E	RW	DCB33DR2	5E	RW	ASC23CR2	9E	RW	INT_MSK3	DE	RW
PRT7DM2	1F	RW	DCB33CR0	5F	#	ASC23CR3	9F	RW	INT_MSK2	DF	RW
DBB00DR0	20	#	AMX_IN	60	RW		A0		INT_MSK0	E0	RW
DBB00DR1	21	W		61			A1		INT_MSK1	E1	RW
DBB00DR2	22	RW		62			A2		INT_VC	E2	RC
DBB00CR0	23	#	ARF_CR	63	RW		A3		RES_WDT	E3	W
DBB01DR0	24	#	CMP_CR0	64	#		A4		DEC_DH	E4	RC
DBB01DR1	25	W	ASY_CR	65	#		A5		DEC_DL	E5	RC
DBB01DR2	26	RW	CMP_CR1	66	RW		A6		DEC_CR0	E6	RW
DBB01CR0	27	#		67			A7		DEC_CR1	E7	RW
DCB02DR0	28	#		68		MUL1_X	A8	W	MULO_X	E8	W
DCB02DR1	29	W		69		MUL1_Y	A9	W	MULO_Y	E9	W
DCB02DR2	2A	RW		6A		MUL1_DH	AA	R	MULO_DH	EA	R
DCB02CR0	2B	#		6B		MUL1_DL	AB	R	MULO_DL	EB	R
DCB03DR0	2C	#	TMP_DR0	6C	RW	ACC1_DR1	AC	RW	ACC0_DR1	EC	RW
DCB03DR1	2D	W	TMP_DR1	6D	RW	ACC1_DR0	AD	RW	ACC0_DR0	ED	RW
DCB03DR2	2E	RW	TMP_DR2	6E	RW	ACC1_DR3	AE	RW	ACC0_DR3	EE	RW
DCB03CR0	2F	#	TMP_DR3	6F	RW	ACC1_DR2	AF	RW	ACC0_DR2	EF	RW
DBB10DR0	30	#	ACB00CR3	70	RW	RD10RI	B0	RW		F0	
DBB10DR1	31	W	ACB00CR0	71	RW	RD10SYN	B1	RW		F1	
DBB10DR2	32	RW	ACB00CR1	72	RW	RD10IS	B2	RW		F2	
DBB10CR0	33	#	ACB00CR2	73	RW	RD10LT0	B3	RW		F3	
DBB11DR0	34	#	ACB01CR3	74	RW	RD10LT1	B4	RW		F4	
DBB11DR1	35	W	ACB01CR0	75	RW	RD10RO0	B5	RW		F5	
DBB11DR2	36	RW	ACB01CR1	76	RW	RD10RO1	B6	RW		F6	
DBB11CR0	37	#	ACB01CR2	77	RW		B7		CPU_F	F7	RL
DCB12DR0	38	#	ACB02CR3	78	RW	RD11RI	B8	RW		F8	
DCB12DR1	39	W	ACB02CR0	79	RW	RD11SYN	B9	RW		F9	
DCB12DR2	3A	RW	ACB02CR1	7A	RW	RD11IS	BA	RW		FA	
DCB12CR0	3B	#	ACB02CR2	7B	RW	RD11LT0	BB	RW		FB	
DCB13DR0	3C	#	ACB03CR3	7C	RW	RD11LT1	BC	RW		FC	
DCB13DR1	3D	W	ACB03CR0	7D	RW	RD11RO0	BD	RW		FD	
DCB13DR2	3E	RW	ACB03CR1	7E	RW	RD11RO1	BE	RW	CPU_SCR1	FE	#
DCB13CR0	3F	#	ACB03CR2	7F	RW		BF		CPU_SCR0	FF	#

Blank fields are Reserved and should not be accessed.

Access is bit specific.

Table 10. Register Map Bank 1 Table: Configuration Space

Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access
PRT0DM0	00	RW	DBB20FN	40	RW	ASC10CR0	80	RW	RDI2RI	C0	RW
PRT0DM1	01	RW	DBB20IN	41	RW	ASC10CR1	81	RW	RDI2SYN	C1	RW
PRT0IC0	02	RW	DBB20OU	42	RW	ASC10CR2	82	RW	RDI2IS	C2	RW
PRT0IC1	03	RW		43		ASC10CR3	83	RW	RDI2LT0	C3	RW
PRT1DM0	04	RW	DBB21FN	44	RW	ASD11CR0	84	RW	RDI2LT1	C4	RW
PRT1DM1	05	RW	DBB21IN	45	RW	ASD11CR1	85	RW	RDI2RO0	C5	RW
PRT1IC0	06	RW	DBB21OU	46	RW	ASD11CR2	86	RW	RDI2RO1	C6	RW
PRT1IC1	07	RW		47		ASD11CR3	87	RW		C7	
PRT2DM0	08	RW	DCB22FN	48	RW	ASC12CR0	88	RW	RDI3RI	C8	RW
PRT2DM1	09	RW	DCB22IN	49	RW	ASC12CR1	89	RW	RDI3SYN	C9	RW
PRT2IC0	0A	RW	DCB22OU	4A	RW	ASC12CR2	8A	RW	RDI3IS	CA	RW
PRT2IC1	0B	RW		4B		ASC12CR3	8B	RW	RDI3LT0	CB	RW
PRT3DM0	0C	RW	DCB23FN	4C	RW	ASD13CR0	8C	RW	RDI3LT1	CC	RW
PRT3DM1	0D	RW	DCB23IN	4D	RW	ASD13CR1	8D	RW	RDI3RO0	CD	RW
PRT3IC0	0E	RW	DCB23OU	4E	RW	ASD13CR2	8E	RW	RDI3RO1	CE	RW
PRT3IC1	0F	RW		4F		ASD13CR3	8F	RW		CF	
PRT4DM0	10	RW	DBB30FN	50	RW	ASD20CR0	90	RW	GDI_O_IN	D0	RW
PRT4DM1	11	RW	DBB30IN	51	RW	ASD20CR1	91	RW	GDI_E_IN	D1	RW
PRT4IC0	12	RW	DBB30OU	52	RW	ASD20CR2	92	RW	GDI_O_OU	D2	RW
PRT4IC1	13	RW		53		ASD20CR3	93	RW	GDI_E_OU	D3	RW
PRT5DM0	14	RW	DBB31FN	54	RW	ASC21CR0	94	RW		D4	
PRT5DM1	15	RW	DBB31IN	55	RW	ASC21CR1	95	RW		D5	
PRT5IC0	16	RW	DBB31OU	56	RW	ASC21CR2	96	RW		D6	
PRT5IC1	17	RW		57		ASC21CR3	97	RW		D7	
PRT6DM0	18	RW	DCB32FN	58	RW	ASD22CR0	98	RW		D8	
PRT6DM1	19	RW	DCB32IN	59	RW	ASD22CR1	99	RW		D9	
PRT6IC0	1A	RW	DCB32OU	5A	RW	ASD22CR2	9A	RW		DA	
PRT6IC1	1B	RW		5B		ASD22CR3	9B	RW		DB	
PRT7DM0	1C	RW	DCB33FN	5C	RW	ASC23CR0	9C	RW		DC	
PRT7DM1	1D	RW	DCB33IN	5D	RW	ASC23CR1	9D	RW	OSC_GO_EN	DD	RW
PRT7IC0	1E	RW	DCB33OU	5E	RW	ASC23CR2	9E	RW	OSC_CR4	DE	RW
PRT7IC1	1F	RW		5F		ASC23CR3	9F	RW	OSC_CR3	DF	RW
DBB00FN	20	RW	CLK_CR0	60	RW		A0		OSC_CR0	E0	RW
DBB00IN	21	RW	CLK_CR1	61	RW		A1		OSC_CR1	E1	RW
DBB00OU	22	RW	ABF_CR0	62	RW		A2		OSC_CR2	E2	RW
	23		AMD_CR0	63	RW		A3		VLT_CR	E3	RW
DBB01FN	24	RW		64			A4		VLT_CMP	E4	R
DBB01IN	25	RW		65			A5			E5	
DBB01OU	26	RW	AMD_CR1	66	RW		A6			E6	
	27		ALT_CR0	67	RW		A7		DEC_CR2	E7	RW
DCB02FN	28	RW	ALT_CR1	68	RW		A8		IMO_TR	E8	W
DCB02IN	29	RW	CLK_CR2	69	RW		A9		ILO_TR	E9	W
DCB02OU	2A	RW		6A			AA		BDG_TR	EA	RW
	2B			6B			AB		ECO_TR	EB	W
DCB03FN	2C	RW	TMP_DR0	6C	RW		AC			EC	
DCB03IN	2D	RW	TMP_DR1	6D	RW		AD			ED	
DCB03OU	2E	RW	TMP_DR2	6E	RW		AE			EE	
	2F		TMP_DR3	6F	RW		AF			EF	
DBB10FN	30	RW	ACB00CR3	70	RW	RDI0RI	B0	RW		F0	
DBB10IN	31	RW	ACB00CR0	71	RW	RDI0SYN	B1	RW		F1	
DBB10OU	32	RW	ACB00CR1	72	RW	RDI0IS	B2	RW		F2	
	33		ACB00CR2	73	RW	RDI0LT0	B3	RW		F3	
DBB11FN	34	RW	ACB01CR3	74	RW	RDI0LT1	B4	RW		F4	
DBB11IN	35	RW	ACB01CR0	75	RW	RDI0RO0	B5	RW		F5	
DBB11OU	36	RW	ACB01CR1	76	RW	RDI0RO1	B6	RW		F6	
	37		ACB01CR2	77	RW		B7		CPU_F	F7	RL
DCB12FN	38	RW	ACB02CR3	78	RW	RDI1RI	B8	RW		F8	
DCB12IN	39	RW	ACB02CR0	79	RW	RDI1SYN	B9	RW		F9	
DCB12OU	3A	RW	ACB02CR1	7A	RW	RDI1IS	BA	RW	FLS_PR1	FA	RW
	3B		ACB02CR2	7B	RW	RDI1LT0	BB	RW		FB	
DCB13FN	3C	RW	ACB03CR3	7C	RW	RDI1LT1	BC	RW		FC	
DCB13IN	3D	RW	ACB03CR0	7D	RW	RDI1RO0	BD	RW		FD	
DCB13OU	3E	RW	ACB03CR1	7E	RW	RDI1RO1	BE	RW	CPU_SCR1	FE	#
	3F		ACB03CR2	7F	RW		BF		CPU_SCR0	FF	#

Blank fields are Reserved and should not be accessed.

Access is bit specific.

Electrical Specifications

This section presents the DC and AC electrical specifications of the CY8C29x66 PSoC device. For the most up-to-date electrical specifications, confirm that you have the most recent datasheet by going to the web at <http://www.cypress.com>.

Specifications are valid for $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$ and $T_J \leq 100\text{ }^{\circ}\text{C}$, except where noted. Refer to Table 26 for the electrical specifications on the internal main oscillator (IMO) using SLIMO mode.

Figure 9. Voltage versus CPU Frequency

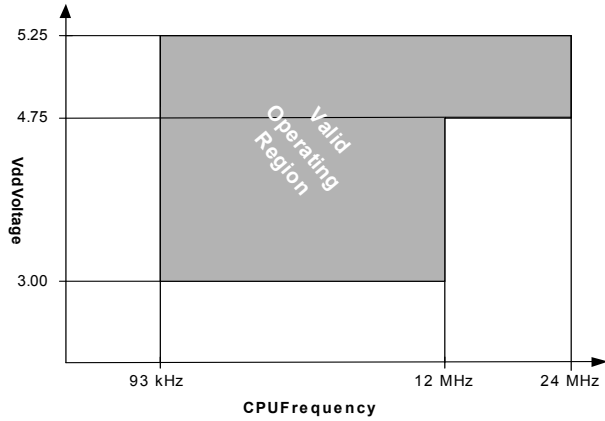
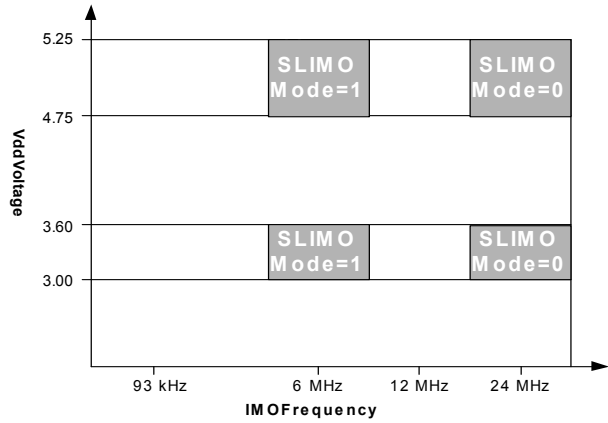


Figure 10. IMO Frequency Options



Absolute Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Table 11. Absolute Maximum Ratings

Symbol	Description	Min	Typ	Max	Unit	Notes
T _{STG}	Storage temperature	-55	25	+100	°C	Higher storage temperatures reduce data retention time. Recommended storage temperature is +25 °C ± 25 °C. Extended duration storage temperatures above 65 °C degrade reliability.
T _{BAKETEMP}	Bake temperature	-	125	See package label	°C	
T _{BAKETIME}	Bake time	See package label	-	72	Hours	
T _A	Ambient temperature with power applied	-40	-	+85	°C	
V _{DD}	Supply voltage on V _{DD} relative to V _{SS}	-0.5	-	+6.0	V	
V _{IO}	DC input voltage	V _{SS} - 0.5	-	V _{DD} + 0.5	V	
V _{IOZ}	DC voltage applied to tristate	V _{SS} - 0.5	-	V _{DD} + 0.5	V	
I _{MIO}	Maximum current into any port pin	-25	-	+50	mA	
I _{MAIO}	Maximum current into any port pin configured as analog driver	-50	-	+50	mA	
ESD	Electro static discharge voltage	2000	-	-	V	Human Body Model ESD.
LU	Latch up current	-	-	200	mA	

Operating Temperature

Table 12. Operating Temperature

Symbol	Description	Min	Typ	Max	Unit	Notes
T _A	Ambient temperature	-40	-	+85	°C	
T _J	Junction temperature	-40	-	+100	°C	The temperature rise from ambient to junction is package specific. See “ Thermal Impedances ” on page 41. You must limit the power consumption to comply with this requirement.

DC Electrical Characteristics

DC Chip-Level Specifications

Table 13 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 13. DC Chip-Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V _{DD}	Supply voltage	3.00	–	5.25	V	See DC POR, SMP, and LVD Specifications on page 26.
I _{DD}	Supply current	–	8	14	mA	Conditions are 5.0 V, T _A = 25°C, CPU = 3 MHz, SYSCLK doubler disabled, VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 0.366 kHz.
I _{DD3}	Supply current	–	5	9	mA	Conditions are V _{DD} = 3.3 V, T _A = 25°C, CPU = 3 MHz, SYSCLK doubler disabled, VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 0.366 kHz.
I _{DDP}	Supply current when IMO = 6 MHz using SLIMO mode.	–	2	3	mA	Conditions are V _{DD} = 3.3 V, T _A = 25°C, CPU = 0.75 MHz, SYSCLK doubler disabled, VC1 = 0.375 MHz, VC2 = 23.44 kHz, VC3 = 0.09 kHz.
I _{SB}	Sleep (Mode) current with POR, LVD, sleep timer, WDT, and internal slow oscillator active.	–	3	10	μA	Conditions are with internal slow speed oscillator, V _{DD} = 3.3 V, $-40\text{ }^{\circ}\text{C} \leq T_A \leq 55\text{ }^{\circ}\text{C}$.
I _{SBH}	Sleep (Mode) current with POR, LVD, sleep timer, WDT, and internal slow oscillator active.	–	4	25	μA	Conditions are with internal slow speed oscillator, V _{DD} = 3.3 V, $55\text{ }^{\circ}\text{C} < T_A \leq 85\text{ }^{\circ}\text{C}$.
I _{SBXTL}	Sleep (Mode) current with POR, LVD, sleep timer, WDT, internal slow oscillator, and 32 kHz crystal oscillator active.	–	4	12	μA	Conditions are with properly loaded, 1 μW max, 32.768 kHz crystal. V _{DD} = 3.3 V, $-40\text{ }^{\circ}\text{C} \leq T_A \leq 55\text{ }^{\circ}\text{C}$.
I _{SBXTLH}	Sleep (Mode) current with POR, LVD, sleep timer, WDT, and 32 kHz crystal oscillator active.	–	5	27	μA	Conditions are with properly loaded, 1 μW max, 32.768 kHz crystal. V _{DD} = 3.3 V, $55\text{ }^{\circ}\text{C} < T_A \leq 85\text{ }^{\circ}\text{C}$.
V _{REF}	Reference voltage (Bandgap)	1.28	1.3	1.32	V	Trimmed for appropriate V _{DD} .

DC General Purpose I/O Specifications

Table 14 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 14. DC GPIO Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
R _{PU}	Pull up resistor	4	5.6	8	kΩ	
R _{PD}	Pull down resistor	4	5.6	8	kΩ	
V _{OH}	High output level	V _{DD} - 1.0	–	–	V	I _{OH} = 10 mA, V _{DD} = 4.75 to 5.25 V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). 80 mA maximum combined I _{OH} budget.
V _{OL}	Low output level	–	–	0.75	V	I _{OL} = 25 mA, V _{DD} = 4.75 to 5.25 V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). 150 mA maximum combined I _{OL} budget.
I _{OH}	High level source current	10	–	–	mA	V _{OH} = V _{DD} - 1.0 V, see the limitations of the total current in the note for V _{OH}
I _{OL}	Low level sink current	25	–	–	mA	V _{OL} = 0.75 V, see the limitations of the total current in the note for V _{OL}
V _{IL}	Input low level	–	–	0.8	V	V _{DD} = 3.0 to 5.25.
V _{IH}	Input high level	2.1	–	–	V	V _{DD} = 3.0 to 5.25.
V _H	Input hysteresis	–	60	–	mV	
I _{IL}	Input leakage (absolute value)	–	1	–	nA	Gross tested to 1 μA.
C _{IN}	Capacitive load on pins as input	–	3.5	10	pF	Package and pin dependent. Temp = 25°C.
C _{OUT}	Capacitive load on pins as output	–	3.5	10	pF	Package and pin dependent. Temp = 25°C.

DC Operational Amplifier Specifications

Table 15 and Table 16 list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 $^{\circ}\text{C}$ and are for design guidance only.

The Operational Amplifier is a component of both the Analog Continuous Time PSoC blocks and the Analog Switched Cap PSoC blocks. The guaranteed specifications are measured in the Analog Continuous Time PSoC block. Typical parameters apply to 5 V at 25 $^{\circ}\text{C}$ and are for design guidance only.

Table 15. 5 V DC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
V_{OSOA}	Input offset voltage (absolute value)	–	1.6	10	mV	
	Power = Low, Opamp Bias = High	–	1.3	8	mV	
	Power = Medium, Opamp Bias = High	–	1.2	7.5	mV	
	Power = High, Opamp Bias = High	–	–	–	–	
TCV_{OSOA}	Average input offset voltage drift	–	7.0	35.0	$\mu\text{V}/^{\circ}\text{C}$	
I_{EBOA}	Input leakage current (Port 0 analog pins)	–	200	–	pA	Gross tested to 1 μA .
C_{INOA}	Input capacitance (Port 0 analog pins)	–	4.5	9.5	pF	Package and pin dependent. Temp = 25 $^{\circ}\text{C}$.
V_{CMOA}	Common mode voltage range. All cases, except highest. Power = High, Opamp Bias = High	0.0	–	V_{DD}	V	
		0.5	–	$V_{DD} - 0.5$	V	
$CMRR_{OA}$	Common mode rejection ratio	60	–	–	dB	
G_{OLOA}	Open loop gain	80	–	–	dB	
$V_{OHIGHOA}$	High output voltage swing (internal signals)	$V_{DD} - 0.01$	–	–	V	
V_{OLOWOA}	Low output voltage swing (internal signals)	–	–	0.1	V	
I_{SOA}	Supply current (including associated AGND buffer)	–	150	200	μA	
	Power = Low, Opamp Bias = Low	–	300	400	μA	
	Power = Low, Opamp Bias = High	–	600	800	μA	
	Power = Medium, Opamp Bias = Low	–	1200	1600	μA	
	Power = Medium, Opamp Bias = High	–	2400	3200	μA	
	Power = High, Opamp Bias = High	–	4600	6400	μA	
$PSRR_{OA}$	Supply Voltage Rejection Ratio	67	80	–	dB	$V_{SS} \leq V_{IN} \leq (V_{DD} - 2.25)$ or $(V_{DD} - 1.25\text{ V}) \leq V_{IN} \leq V_{DD}$.

Table 16. 3.3 V DC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
V_{OSOA}	Input offset voltage (absolute value)	–	1.65	10	mV	
	Power = Low, Opamp Bias = High	–	1.32	8	mV	
	Power = Medium, Opamp Bias = High	–	–	–	–	
	High Power is 5 Volts Only	–	–	–	–	
TCV_{OSOA}	Average input offset voltage drift	–	7.0	35.0	$\mu\text{V}/^{\circ}\text{C}$	
I_{EBOA}	Input leakage current (Port 0 analog pins)	–	200	–	pA	Gross tested to 1 μA .
C_{INOA}	Input capacitance (Port 0 analog pins)	–	4.5	9.5	pF	Package and pin dependent. Temp = 25 $^{\circ}\text{C}$.
V_{CMOA}	Common mode voltage range	0	–	V_{DD}	V	
$CMRR_{OA}$	Common mode rejection ratio	60	–	–	dB	
G_{OLOA}	Open loop gain	80	–	–	dB	
$V_{OHIGHOA}$	High output voltage swing (internal signals)	$V_{DD} - 0.01$	–	–	V	
V_{OLOWOA}	Low output voltage swing (internal signals)	–	–	.01	V	
I_{SOA}	Supply current (including associated AGND buffer)	–	150	200	μA	
	Power = Low, Opamp Bias = Low	–	300	400	μA	
	Power = Low, Opamp Bias = High	–	600	800	μA	
	Power = Medium, Opamp Bias = Low	–	1200	1600	μA	
	Power = Medium, Opamp Bias = High	–	2400	3200	μA	
	Power = High, Opamp Bias = High	–	–	–	–	Not Allowed
$PSRR_{OA}$	Supply voltage rejection ratio	54	80	–	dB	$V_{SS} \leq V_{IN} \leq (V_{DD} - 2.25)$ or $(V_{DD} - 1.25\text{ V}) \leq V_{IN} \leq V_{DD}$.

DC Low Power Comparator Specifications

Table 17 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V at 25 $^{\circ}\text{C}$ and are for design guidance only.

Table 17. DC Low Power Comparator Specifications

Symbol	Description	Min	Typ	Max	Unit
V_{REFLPC}	Low power comparator (LPC) reference voltage range	0.2	–	$V_{DD} - 1$	V
I_{SLPC}	LPC supply current	–	10	40	μA
V_{OSLPC}	LPC voltage offset	–	2.5	30	mV

DC Analog Output Buffer Specifications

Table 18 and Table 19 list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 $^{\circ}\text{C}$ and are for design guidance only.

Table 18. 5 V DC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Unit
V_{OSOB}	Input offset voltage (Absolute Value)	–	3	12	mV
TCV_{OSOB}	Average input offset voltage drift	–	+6	–	$\mu\text{V}/^{\circ}\text{C}$
V_{CMOB}	Common mode input voltage range	0.5	–	$V_{DD} - 1.0$	V
R_{OUTOB}	Output resistance Power = Low Power = High	– –	– –	1 1	W W
$V_{OHIGHOB}$	High output voltage swing (Load = 32 ohms to $V_{DD}/2$) Power = Low Power = High	$0.5 \times V_{DD} + 1.3$ $0.5 \times V_{DD} + 1.3$	– –	– –	V V
V_{OLOWOB}	Low output voltage swing (Load = 32 ohms to $V_{DD}/2$) Power = Low Power = High	– –	– –	$0.5 \times V_{DD} - 1.3$ $0.5 \times V_{DD} - 1.3$	V V
I_{SOB}	Supply current including bias cell (No Load) Power = Low Power = High	– –	1.1 2.6	2 5	mA mA
$PSRR_{OB}$	Supply voltage rejection ratio	40	64	–	dB

Table 19. 3.3 V DC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units
V _{OSOB}	Input offset voltage (absolute value)	–	3	12	mV
TCV _{OSOB}	Average input offset voltage drift	–	+6	–	μV/°C
V _{CMOB}	Common mode input voltage range	0.5	–	V _{DD} – 1.0	V
R _{OUTOB}	Output resistance Power = Low Power = High	– –	– –	10 10	W W
V _{OHIGHOB}	High output voltage swing (Load = 1k ohms to V _{DD/2}) Power = Low Power = High	0.5 × V _{DD} + 1.0 0.5 × V _{DD} + 1.0	– –	– –	V V
V _{OLOWOB}	Low output voltage swing (Load = 1k ohms to V _{DD/2}) Power = Low Power = High	– –	– –	0.5 × V _{DD} – 1.0 0.5 × V _{DD} – 1.0	V V
I _{SOB}	Supply current including bias cell (No Load) Power = Low Power = High	– –	0.8 2.0	1 5	mA mA
PSRR _{OB}	Supply voltage rejection ratio	60	64	–	dB

DC Switch Mode Pump Specifications

Table 20 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

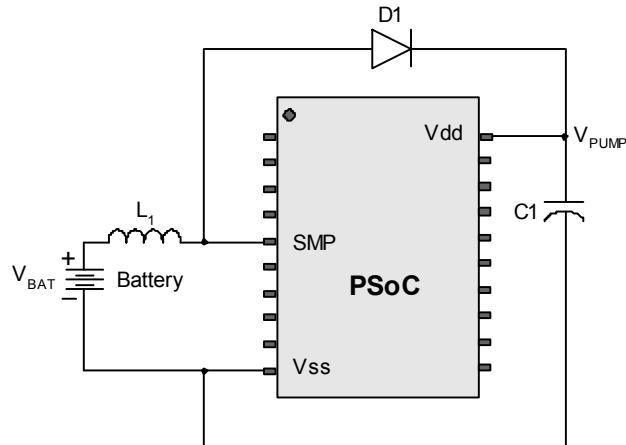
Table 20. DC Switch Mode Pump (SMP) Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
V _{PUMP} 5 V	5 V output voltage at V _{DD} from pump	4.75	5.0	5.25	V	Configured as in Note 10. Average, neglecting ripple. SMP trip voltage is set to 5.0 V.
V _{PUMP} 3 V	3 V output voltage at V _{DD} from pump	3.00	3.25	3.60	V	Configured as in Note 10. Average, neglecting ripple. SMP trip voltage is set to 3.25 V.
I _{PUMP}	Available output current V _{BAT} = 1.5 V, V _{PUMP} = 3.25 V V _{BAT} = 1.8 V, V _{PUMP} = 5.0 V	8 5	– –	– –	mA mA	Configured as in Note 10. SMP trip voltage is set to 3.25 V. SMP trip voltage is set to 5.0 V.
V _{BAT} 5 V	Input voltage range from battery	1.8	–	5.0	V	Configured as in Note 10. SMP trip voltage is set to 5.0 V.
V _{BAT} 3 V	Input voltage range from battery	1.0	–	3.3	V	Configured as in Note 10. SMP trip voltage is set to 3.25 V.
V _{BAT} START	Minimum input voltage from battery to start pump	1.2	–	–	V	Configured as in Note 10. 0°C ≤ T _A ≤ 100. 1.25 V at T _A = –40 °C.
ΔV _{PUMP_Line}	Line regulation (over V _{BAT} range)	–	5	–	%V _O	Configured as in Note 10. V _O is the “V _{DD} Value for PUMP Trip” specified by the VM[2:0] setting in the DC POR and LVD Specification, Table 3-15 on page 27.
ΔV _{PUMP_Load}	Load regulation	–	5	–	%V _O	Configured as in Note 10. V _O is the “V _{DD} Value for PUMP Trip” specified by the VM[2:0] setting in Table 24, “DC POR, SMP, and LVD Specifications,” on page 26.
ΔV _{PUMP_Ripple}	Output voltage ripple (depends on capacitor/load)	–	100	–	mVpp	Configured as in Note 10. Load is 5 mA.
E ₃	Efficiency	35	50	–	%	Configured as in Note 10. Load is 5 mA. SMP trip voltage is set to 3.25 V.
F _{PUMP}	Switching frequency	–	1.4	–	MHz	
DC _{PUMP}	Switching duty cycle	–	50	–	%	

Note

10. L₁ = 2 μH inductor, C₁ = 10 μF capacitor, D₁ = Schottky diode. See Figure 11

Figure 11. Basic Switch Mode Pump Circuit



DC Analog Reference Specifications

Table 21 and Table 22 list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

The guaranteed specifications are measured through the Analog Continuous Time PSoC blocks. The power levels for AGND refer to the power of the Analog Continuous Time PSoC block. The power levels for RefHi and RefLo refer to the Analog Reference Control register. The limits stated for AGND include the offset error of the AGND buffer local to the Analog Continuous Time PSoC block. Reference control power is high.

Note Avoid using P2[4] for digital signaling when using an analog resource that depends on the Analog Reference. Some coupling of the digital signal may appear on the AGND.

Table 21. 5 V DC Analog Reference Specifications

Symbol	Description	Min	Typ	Max	Unit
V _{BG5}	Bandgap voltage reference 5 V	1.28	1.30	1.32	V
–	AGND = V _{DD/2} ^[11]	V _{DD/2} – 0.02	V _{DD/2}	V _{DD/2} + 0.02	V
–	AGND = 2 x BandGap ^[11]	2.52	2.60	2.72	V
–	AGND = P2[4] (P2[4] = V _{DD/2}) ^[11]	P2[4] – 0.013	P2[4]	P2[4] + 0.013	V
–	AGND = BandGap ^[11]	1.27	1.3	1.34	V
–	AGND = 1.6 x BandGap ^[11]	2.03	2.08	2.13	V
–	AGND block to block variation (AGND = V _{DD/2}) ^[11]	– 0.034	0.000	0.034	V
–	RefHi = V _{DD/2} + BandGap	V _{DD/2} + 1.21	V _{DD/2} + 1.3	V _{DD/2} + 1.382	V
–	RefHi = 3 x BandGap	3.75	3.9	4.05	V
–	RefHi = 2 x BandGap + P2[6] (P2[6] = 1.3 V)	P2[6] + 2.478	P2[6] + 2.6	P2[6] + 2.722	V
–	RefHi = P2[4] + BandGap (P2[4] = V _{DD/2})	P2[4] + 1.218	P2[4] + 1.3	P2[4] + 1.382	V
–	RefHi = P2[4] + P2[6] (P2[4] = V _{DD/2} , P2[6] = 1.3 V)	P2[4] + P2[6] – 0.058	P2[4] + P2[6]	P2[4] + P2[6] + 0.058	V
–	RefHi = 2 x BandGap	2.50	2.60	2.70	V
–	RefHi = 3.2 x BandGap	4.02	4.16	4.29	V
–	RefLo = BandGap	BG – 0.082	BG + 0.023	BG + 0.129	V
–	RefLo = 2 x BandGap – P2[6] (P2[6] = 1.3 V)	2 x BG – P2[6] – 0.084	2 x BG – P2[6] + 0.025	2 x BG – P2[6] + 0.134	V
–	RefLo = P2[4] – BandGap (P2[4] = V _{DD/2})	P2[4] – BG – 0.056	P2[4] – BG + 0.026	P2[4] – BG + 0.107	V
–	RefLo = P2[4] – P2[6] (P2[4] = V _{DD/2} , P2[6] = 1.3 V)	P2[4] – P2[6] – 0.057	P2[4] – P2[6] + 0.026	P2[4] – P2[6] + 0.110	V

Note

11. AGND tolerance includes the offsets of the local buffer in the PSoC block. Bandgap voltage is 1.3 V ± 0.02 V.

Table 22. 3.3 V DC Analog Reference Specifications

Symbol	Description	Min	Typ	Max	Unit
V _{BG33}	Bandgap voltage reference 3.3 V	1.28	1.30	1.32	V
–	AGND = V _{DD/2} ^[12]	V _{DD/2} – 0.02	V _{DD/2}	V _{DD/2} + 0.02	V
–	AGND = 2 × BandGap ^[12]	Not Allowed			
–	AGND = P2[4] (P2[4] = V _{DD/2})	P2[4] – 0.009	P2[4]	P2[4] + 0.009	V
–	AGND = BandGap ^[12]	1.27	1.30	1.34	V
–	AGND = 1.6 × BandGap ^[12]	2.03	2.08	2.13	V
–	AGND block to block variation (AGND = V _{DD/2}) ^[12]	– 0.034	0.000	0.034	mV
–	RefHi = V _{DD/2} + BandGap	Not Allowed			
–	RefHi = 3 × BandGap	Not Allowed			
–	RefHi = 2 × BandGap + P2[6] (P2[6] = 0.5 V)	Not Allowed			
–	RefHi = P2[4] + BandGap (P2[4] = V _{DD/2})	Not Allowed			
–	RefHi = P2[4] + P2[6] (P2[4] = V _{DD/2} , P2[6] = 0.5 V)	P2[4] + P2[6] – 0.042	P2[4] + P2[6]	P2[4] + P2[6] + 0.042	V
–	RefHi = 2 × BandGap	2.50	2.60	2.70	V
–	RefHi = 3.2 × BandGap	Not Allowed			
–	RefLo = V _{DD/2} – BandGap	Not Allowed			
–	RefLo = BandGap	Not Allowed			
–	RefLo = 2 × BandGap – P2[6] (P2[6] = 0.5 V)	Not Allowed			
–	RefLo = P2[4] – BandGap (P2[4] = V _{DD/2})	Not Allowed			

DC Analog PSoC Block Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 23. DC Analog PSoC Block Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
R _{CT}	Resistor unit value (continuous time)	–	12.2	–	kΩ	
C _{SC}	Capacitor unit value (switch cap)	–	80	–	fF	

DC POR, SMP, and LVD Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 24. DC POR, SMP, and LVD Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V _{PPOR0R} V _{PPOR1R} V _{PPOR2R}	V _{DD} value for PPOR trip (positive ramp) PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b	–	2.91 4.39 4.55	–	V V V	
V _{PPOR0} V _{PPOR1} V _{PPOR2}	V _{DD} value for PPOR trip (negative ramp) PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b	–	2.82 4.39 4.55	–	V V V	
V _{PH0} V _{PH1} V _{PH2}	PPOR hysteresis PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b	– – –	92 0 0	– – –	mV mV mV	

Note

12. AGND tolerance includes the offsets of the local buffer in the PSoC block. Bandgap voltage is 1.3 V ± 0.02 V.

Table 24. DC POR, SMP, and LVD Specifications (continued)

Symbol	Description	Min	Typ	Max	Units	Notes
V_{LVD0}	V_{DD} value for LVD trip VM[2:0] = 000b	2.86	2.92	2.98 ^[13]	V	
V_{LVD1}	VM[2:0] = 001b	2.96	3.02	3.08	V	
V_{LVD2}	VM[2:0] = 010b	3.07	3.13	3.20	V	
V_{LVD3}	VM[2:0] = 011b	3.92	4.00	4.08	V	
V_{LVD4}	VM[2:0] = 100b	4.39	4.48	4.57	V	
V_{LVD5}	VM[2:0] = 101b	4.55	4.64	4.74 ^[14]	V	
V_{LVD6}	VM[2:0] = 110b	4.63	4.73	4.82	V	
V_{LVD7}	VM[2:0] = 111b	4.72	4.81	4.91	V	
V_{PUMP0}	V_{DD} value for SMP trip VM[2:0] = 000b	2.96	3.02	3.08	V	
V_{PUMP1}	VM[2:0] = 001b	3.03	3.10	3.16	V	
V_{PUMP2}	VM[2:0] = 010b	3.18	3.25	3.32	V	
V_{PUMP3}	VM[2:0] = 011b	4.11	4.19	4.28	V	
V_{PUMP4}	VM[2:0] = 100b	4.55	4.64	4.74	V	
V_{PUMP5}	VM[2:0] = 101b	4.63	4.73	4.82	V	
V_{PUMP6}	VM[2:0] = 110b	4.72	4.82	4.91	V	
V_{PUMP7}	VM[2:0] = 111b	4.90	5.00	5.10	V	

DC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 25. DC Programming Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
I_{DDP}	Supply current during programming or verify	–	10	30	mA	
V_{ILP}	Input low voltage during programming or verify	–	–	0.8	V	
V_{IHP}	Input high voltage during programming or verify	2.2	–	–	V	
I_{ILP}	Input current when applying Vilp to P1[0] or P1[1] during programming or verify	–	–	0.2	mA	Driving internal pull down resistor.
I_{IHP}	Input current when applying Vihp to P1[0] or P1[1] during programming or verify	–	–	1.5	mA	Driving internal pull down resistor.
V_{OLV}	Output low voltage during programming or verify	–	–	$V_{SS} + 0.75$	V	
V_{OHV}	Output high voltage during programming or verify	$V_{DD} - 1.0$	–	V_{DD}	V	
Flash _{ENPB}	Flash endurance (per block)	50,000 ^[15]	–	–	–	Erase/write cycles per block.
Flash _{ENT}	Flash endurance (total) ^[16]	1,800,000	–	–	–	Erase/write cycles.
Flash _{DR}	Flash data retention	10	–	–	Years	

Notes

13. Always greater than 50 mV above PPOR (PORLEV = 00) for falling supply.
14. Always greater than 50 mV above PPOR (PORLEV = 10) for falling supply.
15. The 50,000 cycle flash endurance per block will only be guaranteed if the flash is operating within one voltage range. Voltage ranges are 3.0 V to 3.6 V and 4.75 V to 5.25 V.
16. A maximum of 36 x 50,000 block endurance cycles is allowed. This may be balanced between operations on 36x1 blocks of 50,000 maximum cycles each, 36x2 blocks of 25,000 maximum cycles each, or 36x4 blocks of 12,500 maximum cycles each (to limit the total number of cycles to 36x50,000 and that no single block ever sees more than 50,000 cycles).
For the full industrial range, the user must employ a temperature sensor user module (FlashTemp) and feed the result to the temperature argument before writing. Refer to the Flash APIs application note [AN2015](#) (Design Aids - Reading and Writing PSoC® Flash) for more information.

AC Electrical Characteristics

AC Chip-Level Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Note See the individual user module datasheets for information on maximum frequencies for user modules.

Table 26. AC Chip-Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F _{IMO24}	Internal main oscillator (IMO) frequency for 24 MHz	23.4	24	24.6 ^[17,18,19]	MHz	Trimmed for 5 V or 3.3 V operation using factory trim values. See Figure 10 on page 19. SLIMO Mode = 0.
F _{IMO6}	IMO frequency for 6 MHz	5.5	6	6.5 ^[17,18,19]	MHz	Trimmed for 5 V or 3.3 V operation using factory trim values. See Figure 10 on page 19. SLIMO Mode = 1.
F _{CPU1}	CPU frequency (5 V Nominal)	0.0914	24	24.6 ^[17,18]	MHz	
F _{CPU2}	CPU frequency (3.3 V Nominal)	0.0914	12	12.3 ^[18,19]	MHz	
F _{48M}	Digital PSoC block frequency	0	48	49.2 ^[17,18,20]	MHz	Refer to AC Digital Block Specifications on page 32.
F _{24M}	Digital PSoC block frequency	0	24	24.6 ^[18,20]	MHz	
F _{32K1}	Internal low speed oscillator frequency	15	32	64	kHz	
F _{32K2}	External crystal oscillator	–	32.768	–	kHz	Accuracy is capacitor and crystal dependent. 50% duty cycle
F _{32K_U}	Internal low speed oscillator (ILO) untrimmed frequency	5	–	–	kHz	After a reset and before the M8C starts to run, the ILO is not trimmed. See the System Resets section of the PSoC Technical Reference Manual for details on this timing
F _{PLL}	PLL frequency	–	23.986	–	MHz	A multiple (x732) of crystal frequency.
Jitter24M2	24 MHz period jitter (PLL)	–	–	600	ps	
T _{PLLSLEW}	PLL lock time	0.5	–	10	ms	
T _{PLLSLEWLOW}	PLL lock time for low gain setting	0.5	–	50	ms	
T _{OS}	External crystal oscillator startup to 1%	–	250	500	ms	
T _{OSACC}	External crystal oscillator startup to 100 ppm	–	300	600	ms	The crystal oscillator frequency is within 100 ppm of its final value by the end of the T _{OSACC} period. Correct operation assumes a properly loaded 1 μW maximum drive level 32.768 kHz crystal. 3.0 V ≤ V _{DD} ≤ 5.5 V, -40 °C ≤ T _A ≤ 85 °C.
Jitter32k	32 kHz period jitter	–	100	–	ns	
T _{XRST}	External reset pulse width	10	–	–	μs	
DC24M	24 MHz duty cycle	40	50	60	%	

Notes

17. 4.75 V < V_{DD} < 5.25 V.

18. Accuracy derived from IMO with appropriate trim for V_{DD} range.

19. 3.0 V < V_{DD} < 3.6 V. See application note AN2012 "Adjusting PSoC Microcontroller Trims for Dual Voltage-Range Operation" for information on trimming for operation at 3.3 V.

20. See the individual user module datasheets for information on maximum frequencies for user modules

Table 26. AC Chip-Level Specifications (continued)

Symbol	Description	Min	Typ	Max	Units	Notes
DC _{ILO}	Internal low speed oscillator duty cycle	20	50	80	%	
Step24M	24 MHz trim step size	–	50	–	kHz	
F _{out48M}	48 MHz output frequency	46.8	48.0	49.2 ^[17, 19]	MHz	Trimmed. Using factory trim values.
Jitter24M1	24 MHz period jitter (IMO)	–	600	–	ps	
F _{MAX}	Maximum frequency of signal on row input or row output.	–	–	12.3	MHz	
SR _{POWER_UP}	Power supply slew rate	–	–	250	V/ms	V _{DD} slew rate during power up.
T _{POWERUP}	Time from end of POR to CPU executing code	–	16	100	ms	Power up from 0 V. See the System Resets section of the PSoC Technical Reference Manual.

Figure 12. PLL Lock Timing Diagram

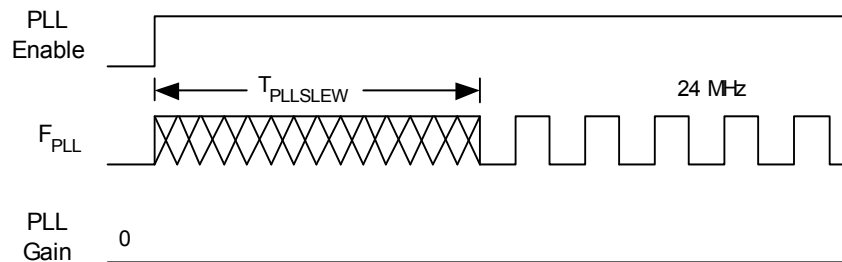


Figure 13. PLL Lock for Low Gain Setting Timing Diagram

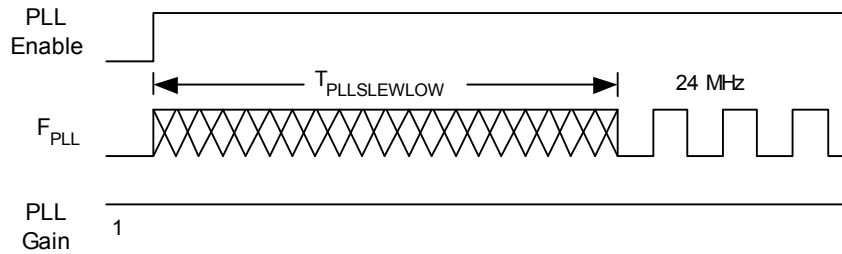


Figure 14. External Crystal Oscillator Startup Timing Diagram

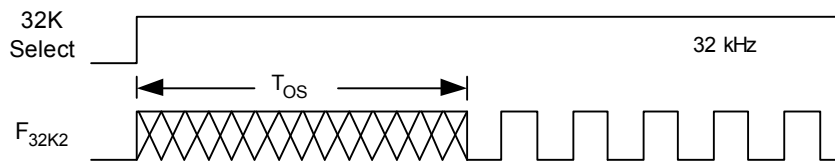
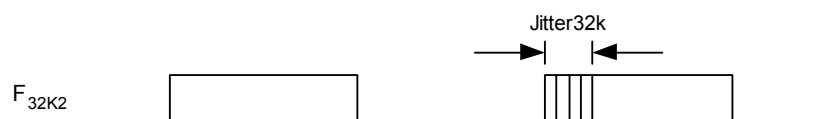


Figure 15. 24 MHz Period Jitter (IMO) Timing Diagram



Figure 0-1. 32 kHz Period Jitter (ECO) Timing Diagram



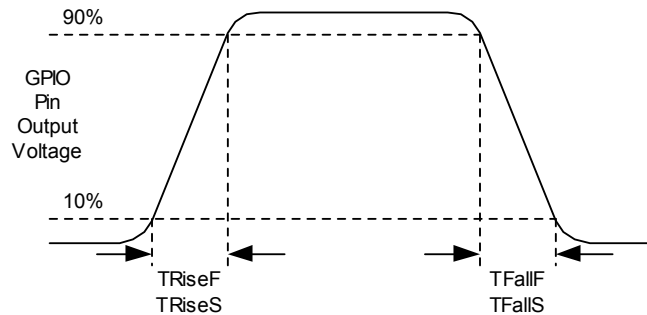
AC General Purpose I/O Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 27. AC GPIO Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
F_{GPIO}	GPIO operating frequency	0	–	12.3	MHz	Normal Strong Mode
T_{RiseF}	Rise time, normal strong mode, $C_{load} = 50\text{ pF}$	3	–	18	ns	$V_{DD} = 4.75\text{ to }5.25\text{ V}$, 10% - 90%
T_{FallF}	Fall time, normal strong mode, $C_{load} = 50\text{ pF}$	2	–	18	ns	$V_{DD} = 4.75\text{ to }5.25\text{ V}$, 10% - 90%
T_{RiseS}	Rise time, slow strong mode, $C_{load} = 50\text{ pF}$	10	27	–	ns	$V_{DD} = 3\text{ to }5.25\text{ V}$, 10% - 90%
T_{FallS}	Fall time, slow strong mode, $C_{load} = 50\text{ pF}$	10	22	–	ns	$V_{DD} = 3\text{ to }5.25\text{ V}$, 10% - 90%

Figure 16. GPIO Timing Diagram



AC Operational Amplifier Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Settling times, slew rates, and gain bandwidth are based on the Analog Continuous Time PSoC block.

Power = High and Opamp Bias = High is not supported at 3.3 V.

Table 28. 5 V AC Operational Amplifier Specifications

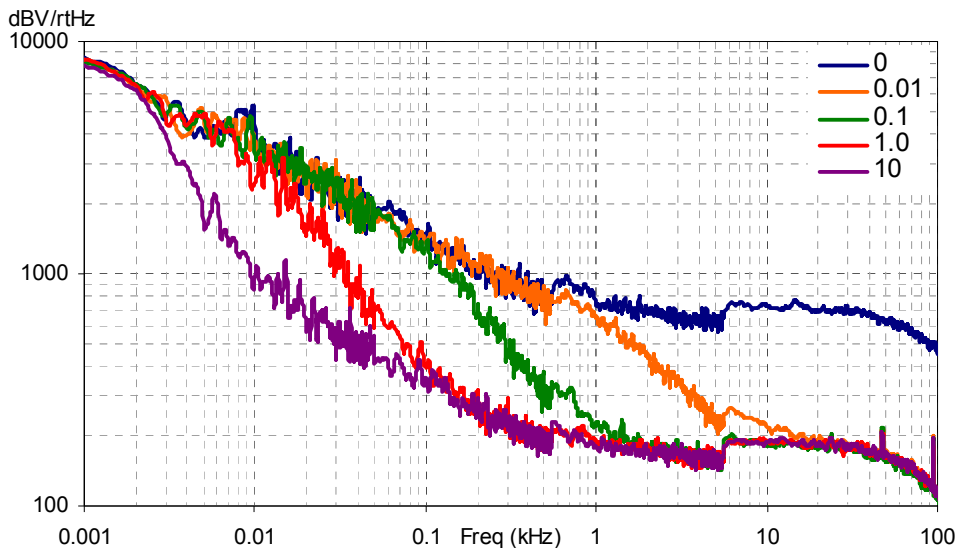
Symbol	Description	Min	Typ	Max	Unit
T_{ROA}	Rising settling time to 0.1% for a 1 V step (10 pF load, unity gain)	–	–	3.9	μs
	Power = Low, Opamp Bias = Low	–	–	0.72	μs
	Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	–	–	0.62	μs
T_{SOA}	Falling settling time to 0.1% for a 1 V step (10 pF load, unity gain)	–	–	5.9	μs
	Power = Low, Opamp Bias = Low	–	–	0.92	μs
	Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	–	–	0.72	μs
SR_{ROA}	Rising slew rate (20% to 80%) of a 1 V step (10 pF load, unity gain)	0.15	–	–	$\text{V}/\mu\text{s}$
	Power = Low, Opamp Bias = Low	1.7	–	–	$\text{V}/\mu\text{s}$
	Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	6.5	–	–	$\text{V}/\mu\text{s}$
SR_{FOA}	Falling slew rate (20% to 80%) of a 1 V step (10 pF load, unity gain)	0.01	–	–	$\text{V}/\mu\text{s}$
	Power = Low, Opamp Bias = Low	0.5	–	–	$\text{V}/\mu\text{s}$
	Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	4.0	–	–	$\text{V}/\mu\text{s}$
BW_{OA}	Gain bandwidth product	0.75	–	–	MHz
	Power = Low, Opamp Bias = Low	3.1	–	–	MHz
	Power = Medium, Opamp Bias = High Power = High, Opamp Bias = High	5.4	–	–	MHz
E_{NOA}	Noise at 1 kHz (Power = Medium, Opamp Bias = High)	–	100	–	$\text{nV}/\text{rt-Hz}$

Table 29. 3.3 V AC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units
T _{ROA}	Rising settling time to 0.1% of a 1 V Step (10 pF load, unity gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	– –	– –	3.92 0.72	μs μs
T _{SOA}	Falling settling time to 0.1% of a 1 V Step (10 pF load, unity gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	– –	– –	5.41 0.72	μs μs
SR _{ROA}	Rising slew rate (20% to 80%) of a 1 V Step (10 pF load, unity gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	0.31 2.7	– –	– –	V/μs V/μs
SR _{FOA}	Falling slew rate (20% to 80%) of a 1 V Step (10 pF load, unity gain) Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	0.24 1.8	– –	– –	V/μs V/μs
BW _{OA}	Gain bandwidth product Power = Low, Opamp Bias = Low Power = Medium, Opamp Bias = High	0.67 2.8	– –	– –	MHz MHz
E _{NOA}	Noise at 1 kHz (Power = Medium, Opamp Bias = High)	–	100	–	nV/rt-Hz

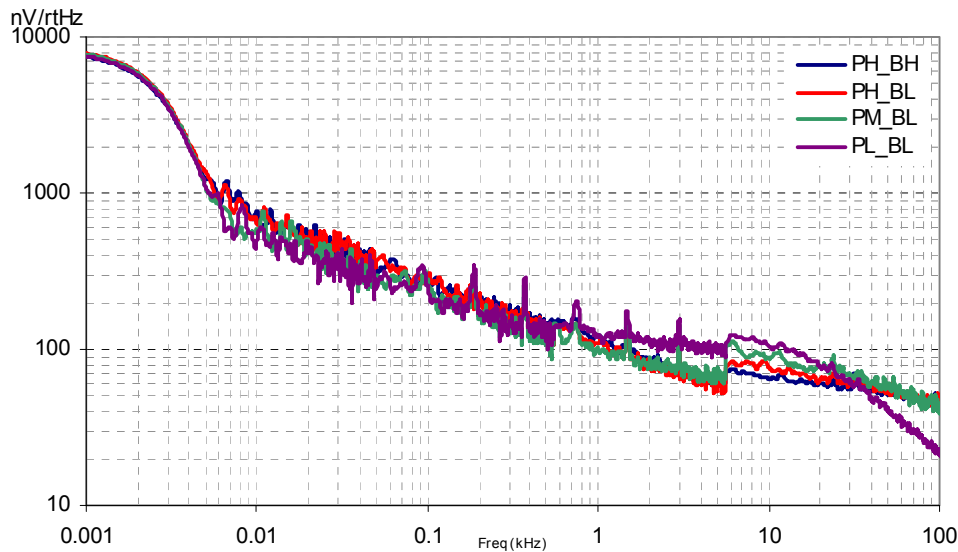
When bypassed by a capacitor on P2[4], the noise of the analog ground signal distributed to each block is reduced by a factor of up to 5 (14 dB). This is at frequencies above the corner frequency defined by the on-chip 8.1k resistance and the external capacitor.

Figure 17. Typical AGND Noise with P2[4] Bypass



At low frequencies, the opamp noise is proportional to $1/f$, power independent, and determined by device geometry. At high frequencies, increased power level reduces the noise spectrum level.

Figure 18. Typical Opamp Noise



AC Low Power Comparator Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V at 25 $^{\circ}\text{C}$ and are for design guidance only.

Table 30. AC Low Power Comparator Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
T_{RLPC}	LPC response time	–	–	50	μs	$\geq 50\text{ mV}$ overdrive comparator reference set within V_{REFLPC} .

AC Digital Block Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 $^{\circ}\text{C}$ and are for design guidance only.

Table 31. AC Digital Block Specifications

Function	Description	Min	Typ	Max	Unit	Notes
All Functions	Maximum block clocking frequency ($> 4.75\text{ V}$)			49.2	MHz	$4.75\text{ V} < V_{DD} < 5.25\text{ V}$.
	Maximum block clocking frequency ($< 4.75\text{ V}$)			24.6	MHz	$3.0\text{ V} < V_{DD} < 4.75\text{ V}$.
Timer	Capture pulse width	50 ^[21]	–	–	ns	
	Maximum frequency, no capture	–	–	49.2	MHz	$4.75\text{ V} < V_{DD} < 5.25\text{ V}$.
	Maximum frequency, with capture	–	–	24.6	MHz	
Counter	Enable pulse width	50 ^[21]	–	–	ns	
	Maximum frequency, no enable input	–	–	49.2	MHz	$4.75\text{ V} < V_{DD} < 5.25\text{ V}$.
	Maximum frequency, enable input	–	–	24.6	MHz	
Dead Band	Kill pulse width:					
	Asynchronous restart mode	20	–	–	ns	
	Synchronous restart mode	50 ^[21]	–	–	ns	
	Disable mode	50 ^[21]	–	–	ns	
	Maximum frequency	–	–	49.2	MHz	$4.75\text{ V} < V_{DD} < 5.25\text{ V}$.

Note

21. 50 ns minimum input pulse width is based on the input synchronizers running at 24 MHz (42 ns nominal period).

Table 31. AC Digital Block Specifications (continued)

Function	Description	Min	Typ	Max	Unit	Notes
CRCPRS (PRS Mode)	Maximum input clock frequency	–	–	49.2	MHz	4.75 V < V _{DD} < 5.25 V.
CRCPRS (CRC Mode)	Maximum input clock frequency	–	–	24.6	MHz	
SPIM	Maximum input clock frequency	–	–	8.2	MHz	Maximum data rate at 4.1 MHz due to 2 x over clocking.
SPIS	Maximum Input Clock Frequency	–	–	4.1	MHz	
	Width of SS_ Negated between transmissions	50 ^[22]	–	–	ns	
Transmitter	Maximum input clock frequency V _{DD} ≥ 4.75 V, 2 stop bits	–	–	24.6	MHz	Maximum data rate at 3.08 MHz due to 8 x over clocking. Maximum data rate at 6.15 MHz due to 8 x over clocking.
		–	–	49.2	MHz	
Receiver	Maximum input clock frequency V _{DD} ≥ 4.75 V, 2 stop bits	–	–	24.6	MHz	Maximum data rate at 3.08 MHz due to 8 x over clocking. Maximum data rate at 6.15 MHz due to 8 x over clocking.
		–	–	49.2	MHz	

AC Analog Output Buffer Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 32. 5 V AC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Unit
T _{ROB}	Rising settling time to 0.1%, 1 V Step, 100 pF load Power = Low Power = High	–	–	4	μs
		–	–	4	μs
T _{SOB}	Falling settling time to 0.1%, 1 V step, 100 pF load Power = Low Power = High	–	–	3.4	μs
		–	–	3.4	μs
SR _{ROB}	Rising slew rate (20% to 80%), 1 V step, 100 pF load Power = Low Power = High	0.5	–	–	V/μs
		0.5	–	–	V/μs
SR _{FOB}	Falling slew rate (80% to 20%), 1 V step, 100 pF load Power = Low Power = High	0.55	–	–	V/μs
		0.55	–	–	V/μs
BW _{OB}	Small signal bandwidth, 20mV _{pp} , 3dB BW, 100 pF load Power = Low Power = High	0.8	–	–	MHz
		0.8	–	–	MHz
BW _{OB}	Large signal bandwidth, 1V _{pp} , 3dB BW, 100 pF load Power = Low Power = High	300	–	–	kHz
		300	–	–	kHz

Table 33. 3.3 V AC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Unit
T _{ROB}	Rising settling time to 0.1%, 1 V Step, 100 pF load Power = Low Power = High	–	–	4.7	μs
		–	–	4.7	μs
T _{SOB}	Falling settling time to 0.1%, 1 V Step, 100 pF load Power = Low Power = High	–	–	4	μs
		–	–	4	μs
SR _{ROB}	Rising slew rate (20% to 80%), 1 V Step, 100 pF load Power = Low Power = High	0.36	–	–	V/μs
		0.36	–	–	V/μs
SR _{FOB}	Falling slew rate (80% to 20%), 1 V Step, 100 pF load Power = Low Power = High	0.40	–	–	V/μs
		0.40	–	–	V/μs

Note

22. 50 ns minimum input pulse width is based on the input synchronizers running at 24 MHz (42 ns nominal period).

Table 33. 3.3 V AC Analog Output Buffer Specifications (continued)

Symbol	Description	Min	Typ	Max	Unit
BW _{OB}	Small signal bandwidth, 20mV _{pp} , 3dB BW, 100 pF load Power = Low Power = High	0.7	–	–	MHz
		0.7	–	–	MHz
BW _{OB}	Large signal bandwidth, 1V _{pp} , 3dB BW, 100 pF load Power = Low Power = High	200	–	–	kHz
		200	–	–	kHz

AC External Clock Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 34. 5 V AC External Clock Specifications

Symbol	Description	Min	Typ	Max	Unit
F _{OSCEXT}	Frequency	0.093	–	24.6	MHz
–	High period	20.6	–	5300	ns
–	Low period	20.6	–	–	ns
–	Power up IMO to switch	150	–	–	ms

Table 35. 3.3 V AC External Clock Specifications

Symbol	Description	Min	Typ	Max	Unit
F _{OSCEXT}	Frequency with CPU clock divide by 1	0.093	–	12.3	MHz
F _{OSCEXT}	Frequency with CPU clock divide by 2 or greater	0.186	–	24.6	MHz
–	High period with CPU clock divide by 1	41.7	–	5300	ns
–	Low period with CPU clock divide by 1	41.7	–	–	ns
–	Power up IMO to switch	150	–	–	μs

AC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 36. AC Programming Specifications

Symbol	Description	Min	Typ	Max	Unit	Notes
T _{RSCLK}	Rise time of SCLK	1	–	20	ns	
T _{FSCLK}	Fall time of SCLK	1	–	20	ns	
T _{SSCLK}	Data setup time to falling edge of SCLK	40	–	–	ns	
T _{HSCLK}	Data hold time from falling edge of SCLK	40	–	–	ns	
F _{SCLK}	Frequency of SCLK	0	–	8	MHz	
T _{ERASEB}	Flash erase time (block)	–	10	–	ms	
T _{WRITE}	Flash block write time	–	40	–	ms	
T _{DSCLK}	Data out delay from falling edge of SCLK	–	–	45	ns	V _{DD} > 3.6
T _{DSCLK3}	Data out delay from falling edge of SCLK	–	–	50	ns	3.0 ≤ V _{DD} ≤ 3.6
T _{ERASEALL}	Flash erase time (Bulk)	–	80	–	ms	Erase all Blocks and protection fields at once
T _{PROGRAM_HOT}	Flash block erase + Flash block write time	–	–	100 ^[23]	ms	0 °C ≤ T _j ≤ 100 °C
T _{PROGRAM_COLD}	Flash block erase + Flash block write time	–	–	200 ^[23]	ms	-40 °C ≤ T _j ≤ 0 °C

Note

23. For the full industrial range, you must employ a temperature sensor user module (FlashTemp) and feed the result to the temperature argument before writing. Refer to the Flash APIs application note AN2015 (Design Aids - Reading and Writing PSoC® Flash) for more information.

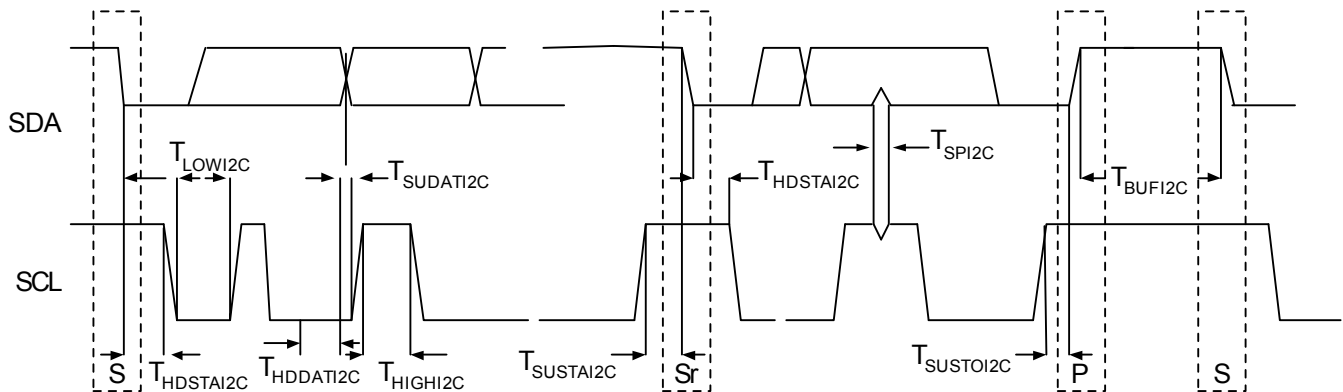
AC I²C Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 37. AC Characteristics of the I²C SDA and SCL Pins

Symbol	Description	Standard Mode		Fast Mode		Unit
		Min	Max	Min	Max	
F _{SCL I2C}	SCL clock frequency	0	100	0	400	kHz
T _{HDSTAI2C}	Hold time (repeated) START condition. After this period, the first clock pulse is generated.	4.0	–	0.6	–	μs
T _{LOWI2C}	LOW period of the SCL clock	4.7	–	1.3	–	μs
T _{HIGHI2C}	HIGH period of the SCL clock	4.0	–	0.6	–	μs
T _{SUSTAI2C}	Setup time for a repeated START condition	4.7	–	0.6	–	μs
T _{HDDATI2C}	Data hold time	0	–	0	–	μs
T _{SUDATI2C}	Data setup time	250	–	100 ^[24]	–	ns
T _{SUSTOI2C}	Setup time for STOP condition	4.0	–	0.6	–	μs
T _{BUFI2C}	Bus free time between a STOP and START condition	4.7	–	1.3	–	μs
T _{SPI2C}	Pulse width of spikes are suppressed by the input filter.	–	–	0	50	ns

Figure 19. Definition for Timing for Fast/Standard Mode on the I2C Bus



Note

24. A Fast-Mode I²C-bus device can be used in a Standard-Mode I²C-bus system, but the requirement $t_{\text{SU;DAT}} \geq 250\text{ ns}$ must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{\text{rmax}} + t_{\text{SU;DAT}} = 1000 + 250 = 1250\text{ ns}$ (according to the Standard-Mode I²C-bus specification) before the SCL line is released.

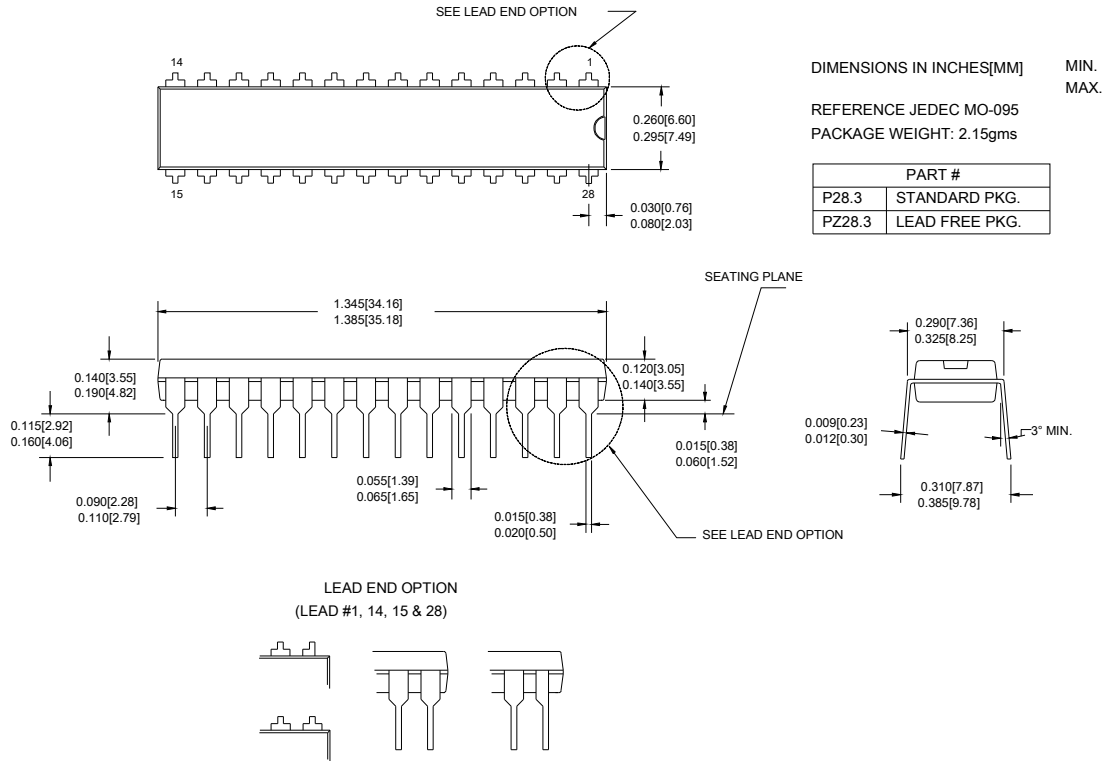
Packaging Information

This section illustrates the packaging specifications for the CY8C29x66 PSoC device, along with the thermal impedances for each package and the typical package capacitance on crystal pins.

Important Note Emulation tools may require a larger area on the target PCB than the chip's footprint. For a detailed description of the emulation tools' dimensions, refer to the emulator pod drawings at <http://www.cypress.com>.

Packaging Dimensions

Figure 20. 28-Pin (300 mil) Molded DIP



51-85014 *E

Figure 21. 28-Pin (210-Mil) SSOP

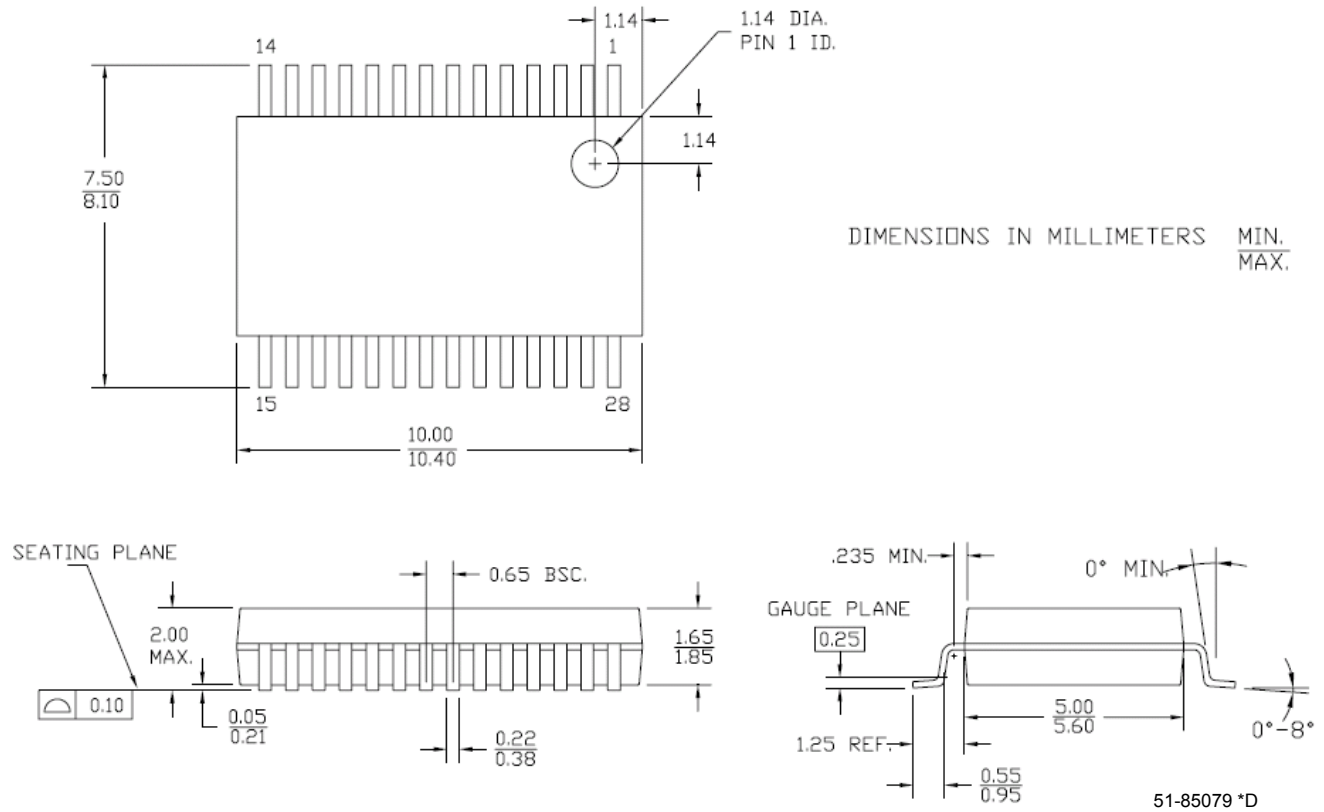


Figure 22. 28-Pin (300-Mil) SOIC

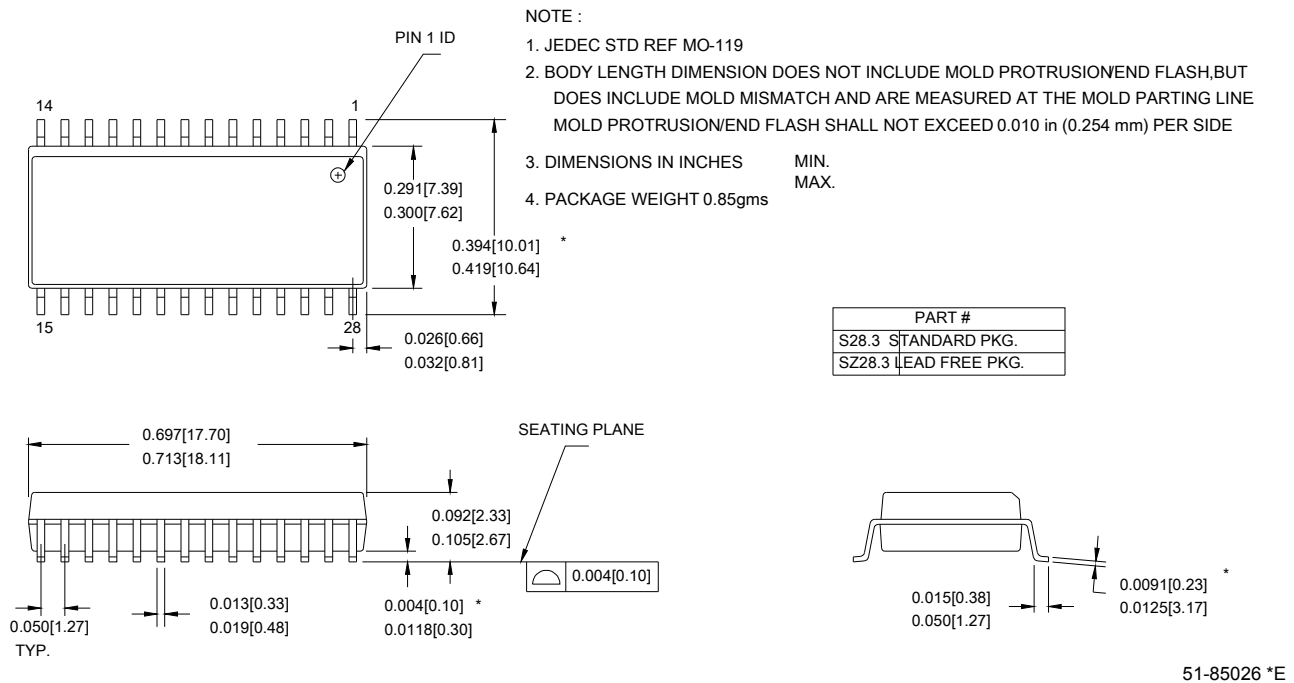
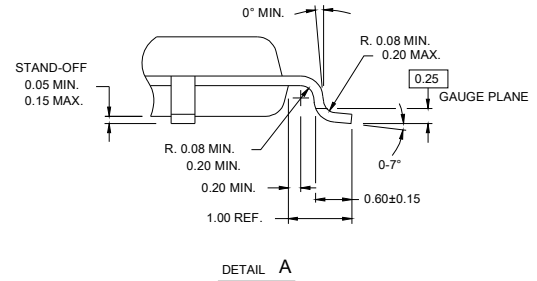
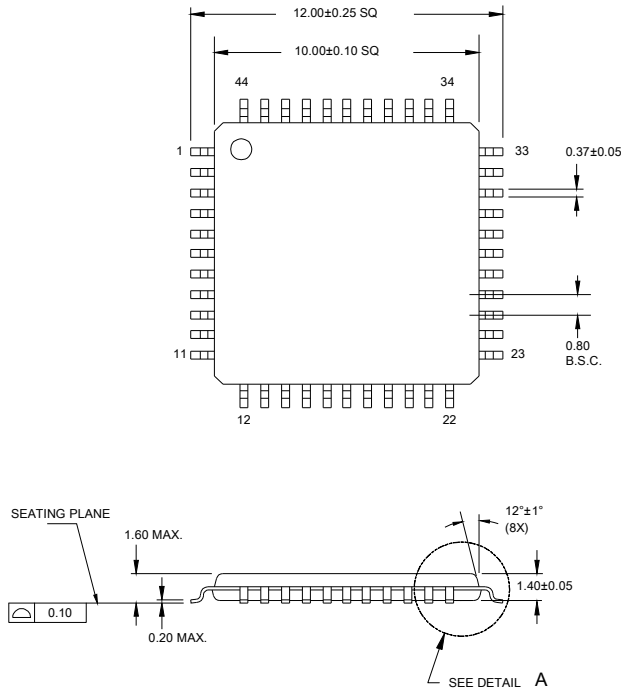


Figure 23. 44-Pin TQFP

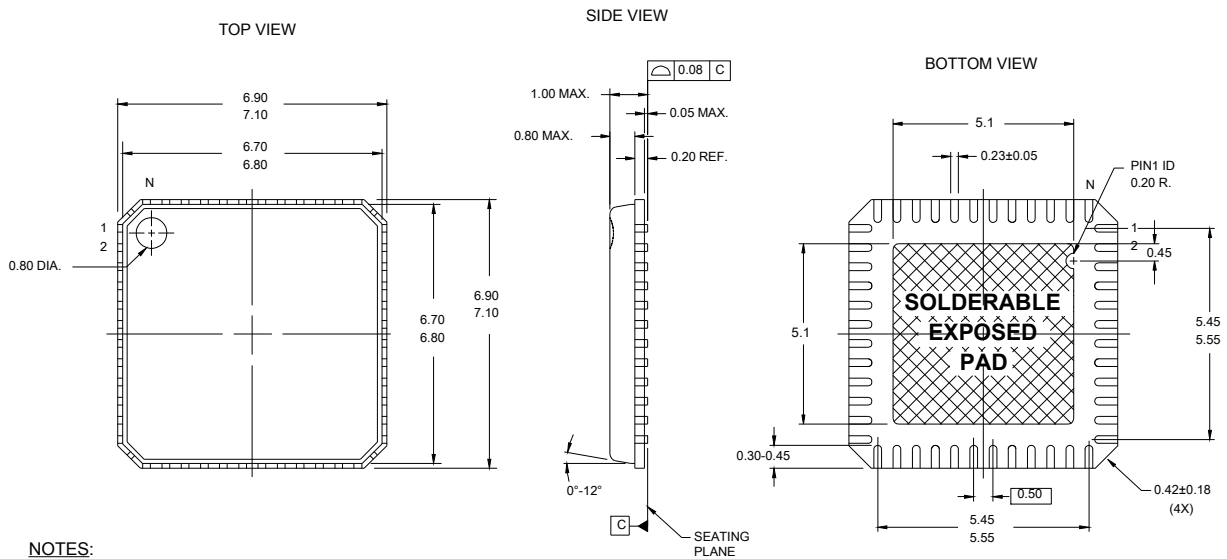


NOTE:


1. JEDEC STD REF MS-026
2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH
MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.0098 in (0.25 mm) PER SIDE
BODY LENGTH DIMENSIONS ARE MAX PLASTIC BODY SIZE INCLUDING MOLD MISMATCH
3. DIMENSIONS IN MILLIMETERS

51-85064 *D

Figure 24. 48-Pin (7 × 7 mm) QFN



NOTES:

1. ATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MO-220
3. PACKAGE WEIGHT: 0.13g
4. ALL DIMENSIONS ARE IN MM [MIN/MAX]
5. PACKAGE CODE

PART #	DESCRIPTION
LF48A	STANDARD
LY48A	LEAD FREE

001-12919 *B

Figure 25. 48-Pin (300-Mil) SSOP

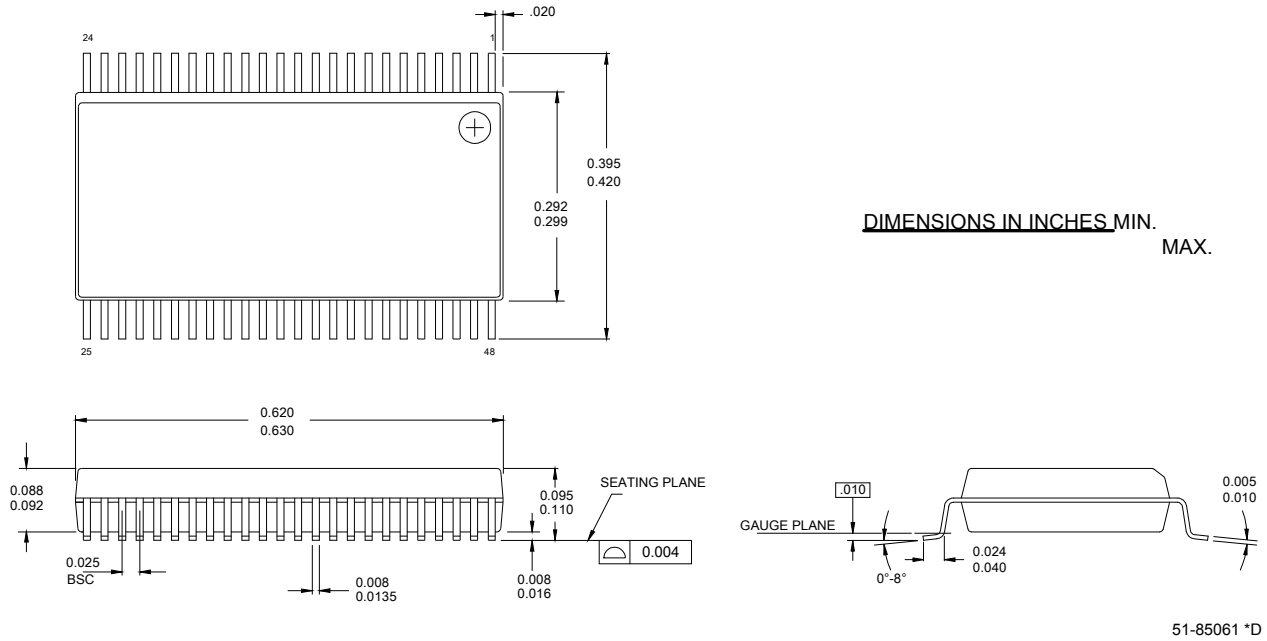
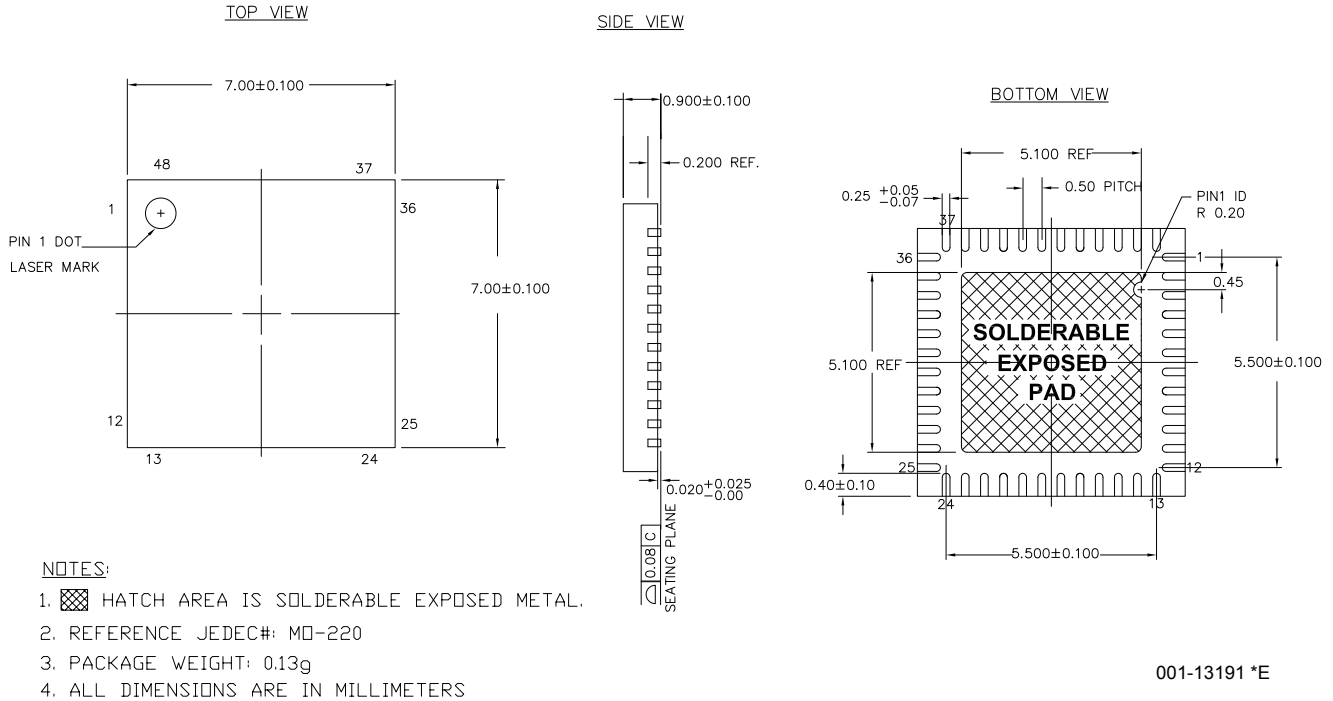


Figure 26. 48-Pin QFN 7 × 7 × 0.90 mm (Sawn Type)



NOTES:


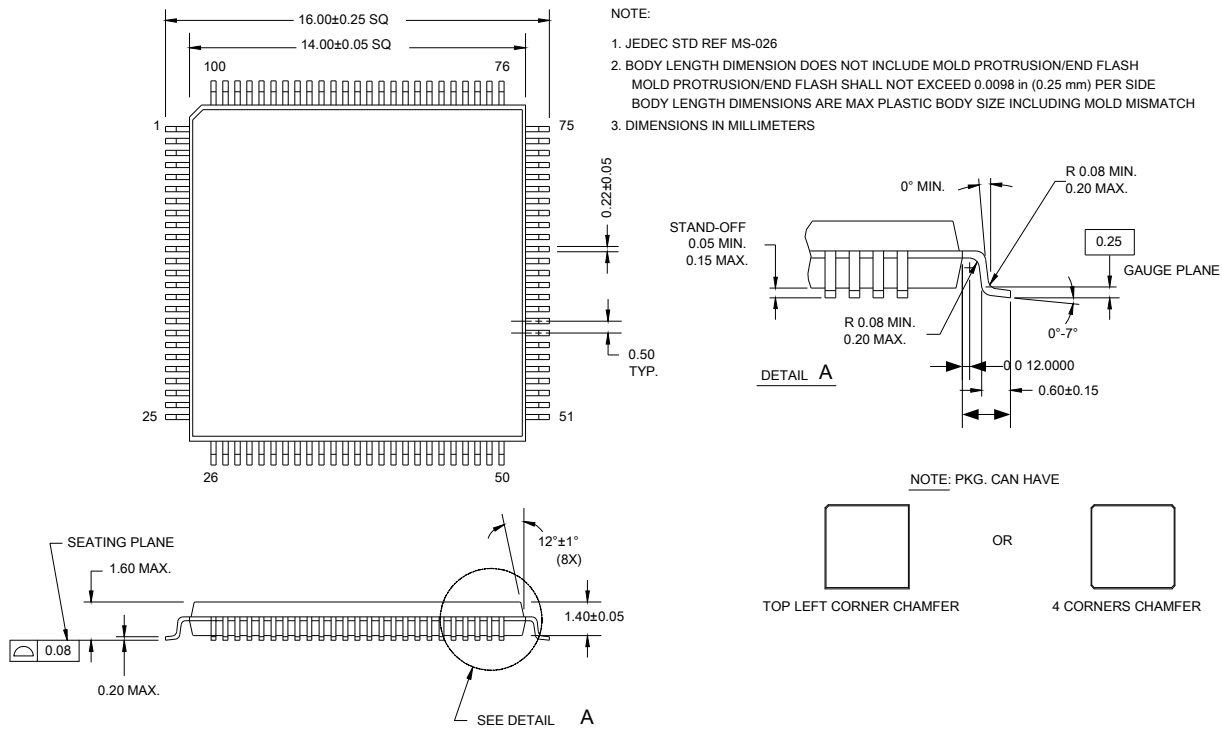
1.  HATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MQ-220
3. PACKAGE WEIGHT: 0.13g
4. ALL DIMENSIONS ARE IN MILLIMETERS

Figure 27. 100-Pin TQFP



Important Note For information on the preferred dimensions for mounting the QFN packages, see the application note “Application Notes for Surface Mount Assembly of Amkor’s MicroLeadFrame (MLF) Packages” available at <http://www.amkor.com>.

Important Note Pinned vias for thermal conduction are not required for the low power PSoC device.

Thermal Impedances

Table 38. Thermal Impedances per Package

Package	Typical θ_{JA} [25]
28-pin PDIP	69 °C/W
28-pin SSOP	94 °C/W
28-pin SOIC	67 °C/W
44-pin TQFP	60 °C/W
48-pin SSOP	69 °C/W
48-pin QFN[26]	28 °C/W
100-pin TQFP	50 °C/W

Capacitance on Crystal Pins

Table 39. Typical Package Capacitance on Crystal Pins

Package	Package Capacitance
28-pin PDIP	3.5 pF
28-pin SSOP	2.8 pF
28-pin SOIC	2.7 pF
44-pin TQFP	2.6 pF
48-pin SSOP	3.3 pF
48-pin QFN	1.8 pF
100-pin TQFP	3.1 pF

Solder Reflow Peak Temperature

Following is the minimum solder reflow peak temperature to achieve good solderability.

Table 40. Solder Reflow Peak Temperature

Package	Minimum Peak Temperature[27]	Maximum Peak Temperature
28-pin PDIP	240 °C	260 °C
28-pin SSOP	240 °C	260 °C
28-pin SOIC	240 °C	260 °C
44-pin TQFP	240 °C	260 °C
48-pin SSOP	240 °C	260 °C
48-pin QFN	240 °C	260 °C
100-pin TQFP	240 °C	260 °C

Notes

25. $T_J = T_A + \text{POWER} \times \theta_{JA}$.

26. To achieve the thermal impedance specified for the QFN package, refer to the application notes for Surface Mount Assembly of Amkor's MicroLeadFrame (MLF) Packages available at <http://www.amkor.com>.

27. Higher temperatures may be required based on the solder melting point. Typical temperatures for solder are $220 \pm 5^\circ\text{C}$ with Sn-Pb or $245 \pm 5^\circ\text{C}$ with Sn-Ag-Cu paste. Refer to the solder manufacturer specifications.

Development Tool Selection

This section presents the development tools available for all current PSoC device families including the CY8C29x66 family.

Software

PSoC Designer™

At the core of the PSoC development software suite is PSoC Designer, used to generate PSoC firmware applications. PSoC Designer is available free of charge at <http://www.cypress.com> and includes a free C compiler.

PSoC Programmer

Flexible enough to be used on the bench in development, yet suitable for factory programming, PSoC Programmer works either as a standalone programming application or it can operate directly from PSoC Designer or PSoC Express. PSoC Programmer software is compatible with both PSoC ICE-Cube In-Circuit Emulator and PSoC MiniProg. PSoC programmer is available free of charge at <http://www.cypress.com>.

Development Kits

All development kits can be purchased from the Cypress Online Store.

CY3215-DK Basic Development Kit

The **CY3215-DK** is for prototyping and development with PSoC Designer. This kit supports in-circuit emulation and the software interface allows users to run, halt, and single step the processor and view the content of specific memory locations. Advance emulation features also supported through PSoC Designer. The kit includes:

- PSoC Designer software CD
- ICE-Cube In-Circuit Emulator
- ICE Flex-Pod for CY8C29x66 family
- Cat-5 adapter
- Mini-Eval programming board
- 110 ~ 240 V power supply, Euro-Plug adapter
- iMAGEcraft C compiler
- ISSP cable
- USB 2.0 cable and Blue Cat-5 cable
- Two CY8C29466-24PXI 28-PDIP chip samples

Evaluation Tools

All evaluation tools can be purchased from the Cypress online store.

CY3210-MiniProg1

The **CY3210-MiniProg1 kit** allows a user to program PSoC devices via the MiniProg1 programming unit. The MiniProg is a small, compact prototyping programmer that connects to the PC via a provided USB 2.0 cable. The kit includes:

- MiniProg programming unit
- MiniEval socket programming and evaluation board
- 28-pin CY8C29466-24PXI PDIP PSoC device sample
- 28-pin CY8C27443-24PXI PDIP PSoC device sample
- PSoC Designer software CD
- Getting Started Guide
- USB 2.0 cable

CY3210-PSoCEval1

The **CY3210-PSoCEval1 kit** features an evaluation board and the MiniProg1 programming unit. The evaluation board includes an LCD module, potentiometer, LEDs, and plenty of bread-boarding space to meet all of your evaluation needs. The kit includes:

- Evaluation board with LCD module
- MiniProg programming unit
- 28-Pin CY8C29466-24PXI PDIP PSoC Device Sample (2)
- PSoC Designer software CD
- Getting Started Guide
- USB 2.0 cable

CY3214-PSoCEvalUSB

The **CY3214-PSoCEvalUSB evaluation kit** features a development board for the CY8C24794-24LFXI PSoC device. Special features of the board include both USB and capacitive sensing development and debugging support. This evaluation board also includes an LCD module, potentiometer, LEDs, an enunciator and plenty of bread boarding space to meet all of your evaluation needs. The kit includes:

- PSoCEvalUSB board
- LCD module
- MiniProg programming unit
- Mini USB cable
- PSoC Designer and example projects CD
- Getting Started Guide
- Wire pack

Device Programmers

All device programmers can be purchased from the Cypress Online Store.

CY3216 Modular Programmer

The [CY3216 Modular Programmer kit](#) features a modular programmer and the MiniProg1 programming unit. The modular programmer includes three programming module cards and supports multiple Cypress products. The kit includes:

- Modular programmer base
- Three programming module cards
- MiniProg programming unit
- PSoC Designer software CD
- Getting Started Guide
- USB 2.0 cable

CY3207ISSP In-System Serial Programmer (ISSP)

The [CY3207ISSP](#) is a production programmer. It includes protection circuitry and an industrial case that is more robust than the MiniProg in a production-programming environment.

Note CY3207ISSP needs special software and is not compatible with PSoC Programmer. The kit includes:

- CY3207 programmer unit
- PSoC ISSP software CD
- 110 ~ 240 V power supply, Euro-Plug adapter
- USB 2.0 cable

Accessories (Emulation and Programming)

Table 41. Emulation and Programming Accessories

Part #	Pin Package	Flex-Pod Kit ^[28]	Foot Kit ^[29]	Adapter ^[30]
CY8C29466-24PXI	28 PDIP	CY3250-29XXX	CY3250-28PDIP-FK	Adapters can be found at http://www.emulation.com .
CY8C29466-24PVXI	28 SSOP	CY3250-29XXX	CY3250-28SSOP-FK	
CY8C29466-24SXI	28 SOIC	CY3250-29XXX	CY3250-28SOIC-FK	
CY8C29566-24AXI	44 TQFP	CY3250-29XXX	CY3250-44TQFP-FK	
CY8C29666-24PVXI	48 SSOP	CY3250-29XXX	CY3250-48SSOP-FK	
CY8C29666-24LFXI	48 QFN	CY3250-29XXXQFN	CY3250-48QFN-FK	
CY8C29666-24LTXI	48 QFN	CY3250-29XXXQFN	CY3250-48QFN-FK	
CY8C29866-24AXI	100 TQFP	CY3250-29XXX	CY3250-100TQFP-FK	

Notes

28. Flex-Pod kit includes a practice flex-pod and a practice PCB, in addition to two flex-pods.

29. Foot kit includes surface mount feet that can be soldered to the target PCB.

30. Programming adapter converts non-DIP package to DIP footprint. Specific details and ordering information for each of the adapters can be found at <http://www.emulation.com>

Ordering Information

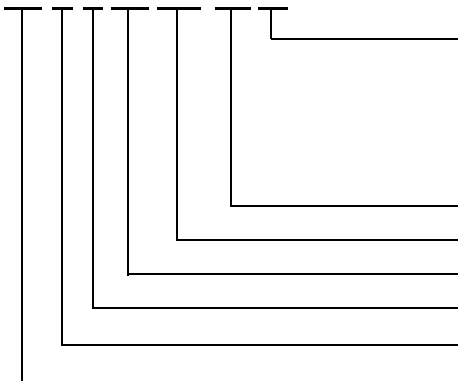
The following table lists the CY8C29x66 PSoC device's key package features and ordering codes.

Package	Ordering Code	Flash (KB)	RAM (KB)	Switch Mode Pump	Temperature Range	Digital PSoC Blocks	Analog PSoC Blocks	Digital I/O Pins	Analog Inputs	Analog Outputs	XRES Pin
28-Pin (300 Mil) DIP	CY8C29466-24PXI	32	2	Yes	-40°C to +85°C	16	12	24	12	4	Yes
28-Pin (210 Mil) SSOP	CY8C29466-24PVXI	32	2	Yes	-40°C to +85°C	16	12	24	12	4	Yes
28-Pin (210 Mil) SSOP (Tape and Reel)	CY8C29466-24PVXIT	32	2	Yes	-40°C to +85°C	16	12	24	12	4	Yes
28-Pin (300 Mil) SOIC	CY8C29466-24SXI	32	2	Yes	-40°C to +85°C	16	12	24	12	4	Yes
28-Pin (300 Mil) SOIC (Tape and Reel)	CY8C29466-24SXIT	32	2	Yes	-40°C to +85°C	16	12	24	12	4	Yes
44-Pin TQFP	CY8C29566-24AXI	32	2	Yes	-40°C to +85°C	16	12	40	12	4	Yes
44-Pin TQFP (Tape and Reel)	CY8C29566-24AXIT	32	2	Yes	-40°C to +85°C	16	12	40	12	4	Yes
48-Pin (300 Mil) SSOP	CY8C29666-24PVXI	32	2	Yes	-40°C to +85°C	16	12	44	12	4	Yes
48-Pin (300 Mil) SSOP (Tape and Reel)	CY8C29666-24PVXIT	32	2	Yes	-40°C to +85°C	16	12	44	12	4	Yes
48-Pin QFN	CY8C29666-24LFXI	32	2	Yes	-40°C to +85°C	16	12	44	12	4	Yes
100-Pin TQFP	CY8C29866-24AXI	32	2	Yes	-40°C to +85°C	16	12	64	12	4	Yes
100-Pin OCD TQFP ^[31]	CY8C29000-24AXI	32	2	Yes	-40°C to +85°C	16	12	64	12	4	Yes
48-Pin (7X7X 1.0 mm) QFN (Sawn)	CY8C29666-24LTXI	32	2	Yes	-40°C to +85°C	16	12	44	12	4	Yes
48-Pin (7X7X 1.0 mm) QFN (Sawn)	CY8C29666-24LTXIT	32	2	Yes	-40°C to +85°C	16	12	44	12	4	Yes

Note For Die sales information, contact a local Cypress sales office or Field Applications Engineer (FAE).

Ordering Code Definitions

CY 8 C 29 xxx-SPxx



Package Type:
 PX = PDIP Pb-free
 SX = SOIC Pb-free
 PVX = SSOP Pb-free
 LFX/LKX/LTX/LQX/LCX = QFN Pb-free
 AX = TQFP Pb-free

Speed: 24 MHz

Part Number

Family Code

Technology Code: C = CMOS

Marketing Code: 8 = Cypress PSoC

Company ID: CY = Cypress

Thermal Rating:
 C = Commercial
 I = Industrial
 E = Extended

Note

31. This part may be used for in-circuit debugging. It is NOT available for production.

Document Conventions

Acronyms Used

Table 42 lists the acronyms used in this datasheet.

Table 42. Acronyms

Acronym	Description
AC	alternating current
ADC	analog-to-digital converter
API	application programming interface
CPU	central processing unit
CT	continuous time
DAC	digital-to-analog converter
DC	direct current
EEPROM	electrically erasable programmable read-only memory
FSR	full scale range
GPIO	general purpose I/O
ICE	in-circuit emulator
IDE	integrated development environment
I/O	input/output
ISSP	in-system serial programming
IPOR	imprecise power on reset
LSb	least-significant bit
LVD	low voltage detect
MSb	most-significant bit
PC	program counter
PGA	programmable gain amplifier
POR	power on reset
PPOR	precision power on reset
PSoC [®]	Programmable System-on-Chip™
PWM	pulse width modulator
ROM	read only memory
SC	switched capacitor
SMP	switch mode pump
SRAM	static random access memory

Units of Measure

Table 43. Units of Measure

Symbol	Unit of Measure
°C	degree Celsius
dB	decibels
fF	femto farad
Hz	hertz
KB	1024 bytes
Kbit	1024 bits
kHz	kilohertz
kΩ	kilohm
MHz	megahertz
MΩ	megaohm
μA	microampere
μF	microfarad
μH	microhenry
μs	microsecond
μV	microvolts
μVrms	microvolts root-mean-square
μW	microwatts
mA	milli-ampere
ms	milli-second
mV	milli-volts
nA	nanoampere
ns	nanosecond
nV	nanovolts
Ω	ohm
pA	picoampere
pF	picofarad
pp	peak-to-peak
ppm	parts per million
ps	picosecond
sps	samples per second
σ	sigma: one standard deviation
V	volts

Numeric Naming

Hexadecimal numbers are represented with all letters in uppercase with an appended lowercase 'h' (for example, '14h' or '3Ah'). Hexadecimal numbers may also be represented by a '0x' prefix, the C coding convention. Binary numbers have an appended lowercase 'b' (for example, '01010100b' or '01000011b'). Numbers not indicated by an 'h', 'b', or 0x are decimals.

Document History Page

Document Title: CY8C29466, CY8C29566, CY8C29666, and CY8C29866 PSoC® Programmable System-on-Chip™ Document Number: 38-12013				
Revision	ECN No.	Submission Date	Origin of Change	Description of Change
**	131151	11/13/2003	New Silicon	New document (Revision **).
*A	132848	01/21/2004	NWJ	New information. First edition of preliminary datasheet.
*B	133205	01/27/2004	NWJ	Changed part numbers, increased SRAM data storage to 2K bytes.
*C	133656	02/09/2004	SFV	Changed part numbers and removed a 28-pin SOIC.
*D	227240	06/01/2004	SFV	Changes to Overview section, 48-pin MLF pinout, and significant changes to the Electrical Specs.
*E	240108	See ECN	SFV	Added a 28-lead (300 mil) SOIC part.
*F	247492	See ECN	SFV	New information added to the Electrical Specifications chapter.
*G	288849	See ECN	HMT	Add DS standards, update device table, fine-tune pinouts, add Reflow Peak Temp. table. Finalize.
*H	722736	See ECN	HMT	Add QFN package clarifications. Add new QFN diagram. Add Low Power Comparator (LPC) AC/DC electrical spec. tables. Add CY8C20x34 to PSoC Device Characteristics table. Update emulation pod/feet kit part numbers. Add OCD non-production pinouts and package diagrams. Add ISSP note to pinout tables. Update package diagram revisions. Update typical and recommended Storage Temperature per industrial specs. Update CY branding and QFN convention. Add new Dev. Tool section. Update copyright and trademarks.
*I	2503350	See ECN	DFK/PYRS	Pinout for CY8C29000 OCD wrongly included details of CY8C24X94. The correct pinout for CY8C29000 is included in this version. Added note on digital signaling in "DC Analog Reference Specifications" section.
*J	2545030	07/29/08	YARA	Added note to Ordering Information
*K	2708295	04/22/2009	JVY	Changed title from "CY8C29466, CY8C29566, CY8C29666, and CY8C29866 PSoC Mixed Signal Array Final datasheet" to "CY8C29466, CY8C29566, CY8C29666, and CY8C29866 PSoC® Programmable System-on-Chip™" Updated to datasheet template Added 48-Pin QFN (Sawn) package diagram and CY8C29666-24LTXI and CY8C29666-24LTXIT part details in the Ordering Information table Updated DC GPIO, AC Chip-Level, and AC Programming Specifications as follows: Modified F _{IMO6} (page 27), T _{WRITE} specifications (page 34) Added I _{OH} (page 21), I _{OL} (page 21), DC _{ILO} (page 28), F _{32K_U} (page 27), T _{POWERUP} (page 28), T _{ERASEALL} (page 34), T _{PROGRAM_HOT} (page 34), and T _{PROGRAM_COLD} (page 34) specifications
*L	2761941	09/10/2009	DRSW/AESA	Added SR _{POWER_UP} parameter in AC specs table.
*M	2842762	01/08/2010	DRSW	Corrected Notes for V _{DD} parameter in Table 13, "DC Chip-Level Specifications," on page 21. Added "Contents" on page 2. Updated links in Sales, Solutions, and Legal Information.

Document Title: CY8C29466, CY8C29566, CY8C29666, and CY8C29866 PSoC® Programmable System-on-Chip™ Document Number: 38-12013				
Revision	ECN No.	Submission Date	Origin of Change	Description of Change
*N	2902396	03/30/2010	NJF	Updated Digital System Block Diagram and content in Digital System Updated Cypress website links. Removed reference to PSoC Designer 4.4 in PSoC Designer Software Subsystems Added T _{BAKETEMP} and T _{BAKETIME} parameters in Absolute Maximum Ratings Updated AC Chip-Level Specifications Changed unit for SPIS function to ns in AC Digital Block Specifications Updated notes in Packaging Information and package diagrams. Updated Solder Reflow Peak Temperature Updated Emulation and Programming Accessories Removed Third Party Tools and Build a PSoC Emulator into Your Board. Updated Ordering Information and Ordering Code Definitions .
*O	2940410	05/31/2010	YJI	Updated content to match current style guide and datasheet template. No technical updates.

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